

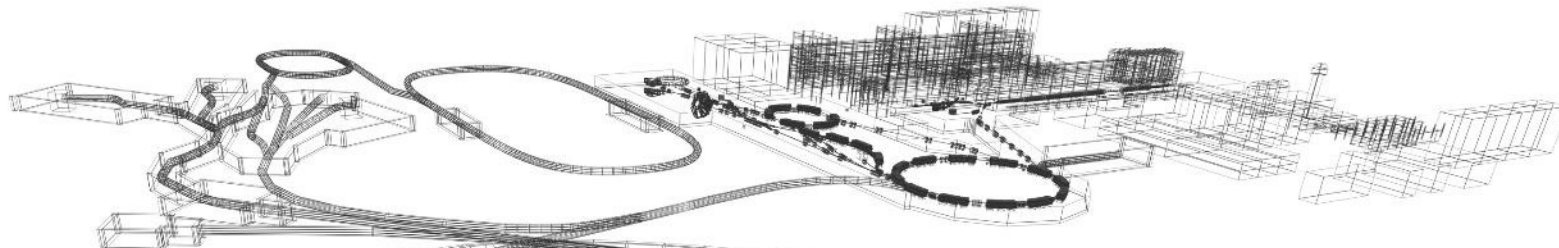
# **News from CMOS Sensors: MIMOSIS and CE-65nm**



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No. 671072



(05P19RFFC1)



Slides are courtesy of M. Deveaux

# News from MIMOSIS

A. Besson, M. Deveaux, Ziad EL BITAR for the CBM-MVD collaboration

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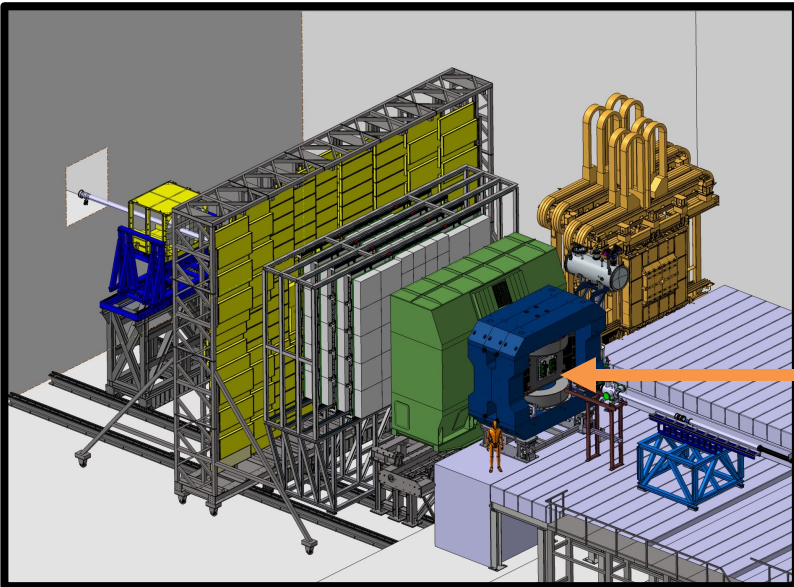
<sup>4</sup>Helmholtz Forschungsakademie Hessen für FAIR, Germany

<sup>5</sup>IJCLab, UMR9012 – CNRS / Université Paris-Saclay / Université de Paris, France

<sup>6</sup>Facility for Antiproton and Ion Research in Europe GmbH, Germany

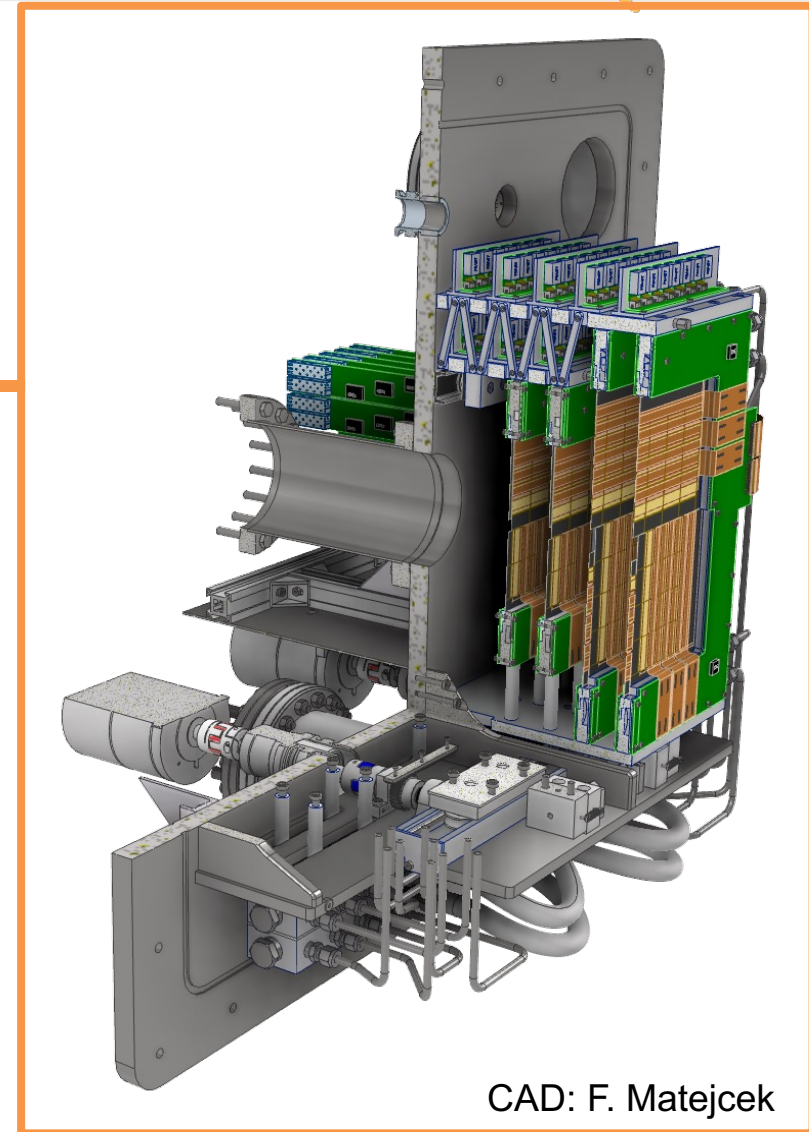


Measurements leading to these results have been performed at the Test Beam Facility at DESY Hamburg (Germany), a member of the Helmholtz Association (HGF)



## Missions for the CBM MVD:

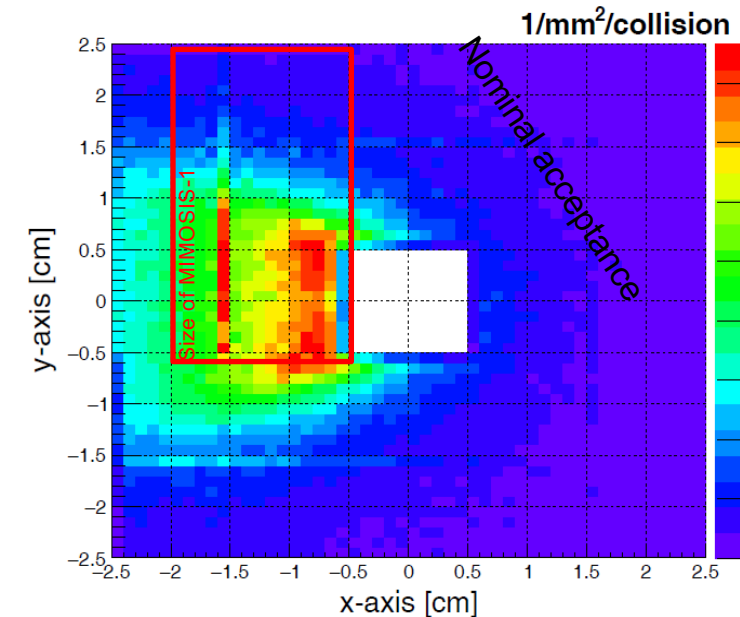
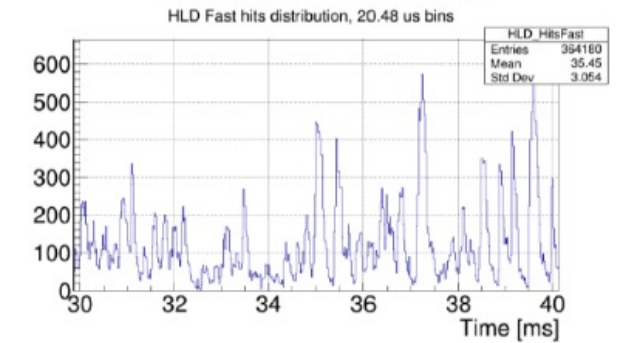
- Low-momentum tracking.
- Conversion electron suppression.
  - Vector meson reconstruction.
- Hyperon reconstruction.
- Open-charm reconstruction.
- High particle rates => Max. 10 MHz  $p+p$   
100 kHz Au+Au



CAD: F. Matejcek

	Requirements
Spatial, time resolution	$\sim 5 \mu\text{m}, 5 \mu\text{s}$
Sensor thickness	$\sim 50 \mu\text{m}$
Power dissipation	$< 100 \text{ mW/cm}^2$
Radiation doses	$7 \times 10^{13} \text{ n}_{\text{eq}}/\text{cm}^2$ $\sim 5 \text{ MRad}$
Radiation gradient over sensor	$\sim 100\%$
Heavy ion tolerance	$1 \text{ kHz/cm}^2$
Rate (average/ 50 $\mu\text{s}$ peak)	$20 / 80 \text{ MHz/cm}^2$

kHz modulation ON





## MIMOSIS-0 (2018)

- Demonstrate pixel concept. ✓
- Demonstrate zero suppression. ✓
- Demonstrate readout concept. ✓



## MIMOSIS-1 (2020)

- Full dimension sensor ✓
- Add buffer structure. ✓
- SEE hardening 1/2 ✓



## MIMOSIS-2 (Q2/2023)

- On-chip pixel grouping.
- Final pixels.
- SEE hardening 2/2



## MIMOSIS-2.1 (Q2/2024)

## MIMOSIS-3

- Final sensor for mass production



Add features  
Fix issues  
Design optimization



Add features  
Fix issues  
Design optimization



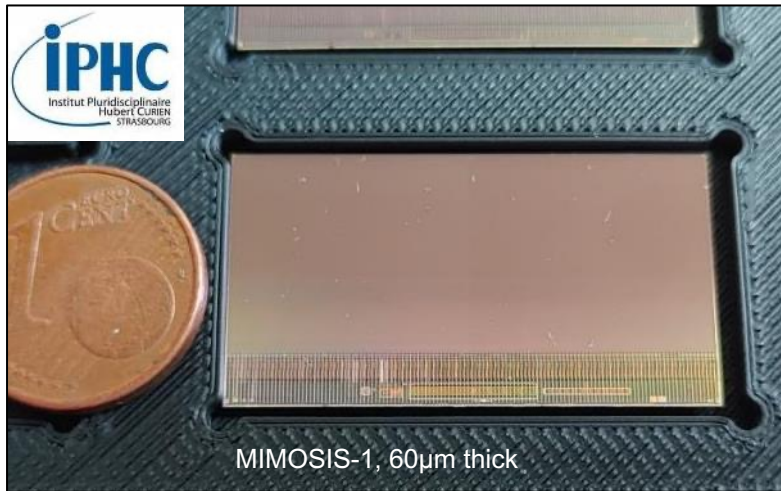
Fix issues



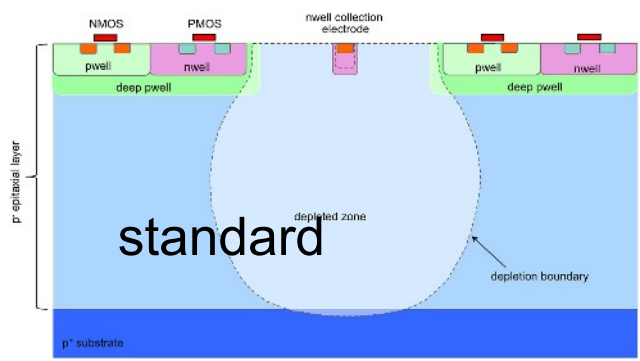
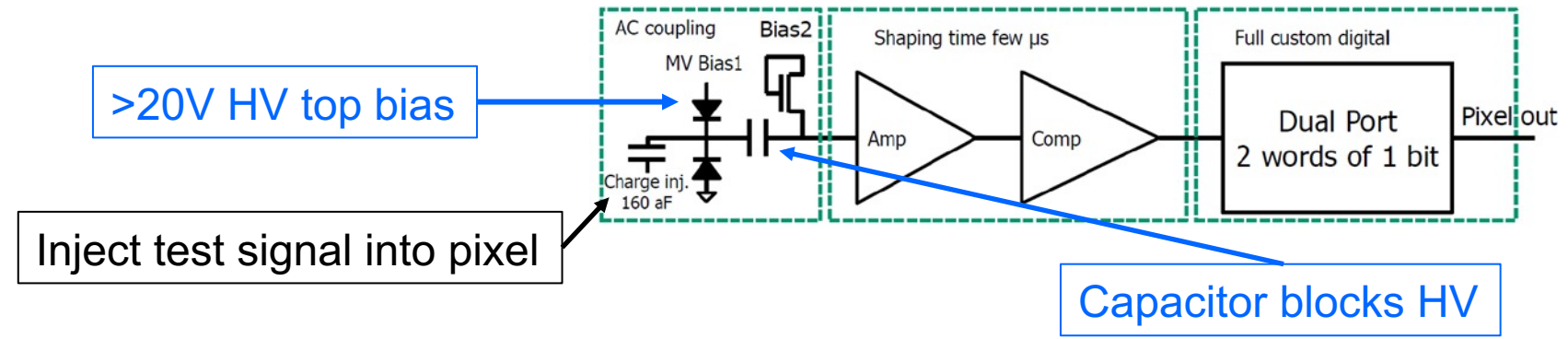
Final design choice  
Fix issues

**We are here**

# MIMOSIS, the sensor for the MVD (inspired by ALPIDE)

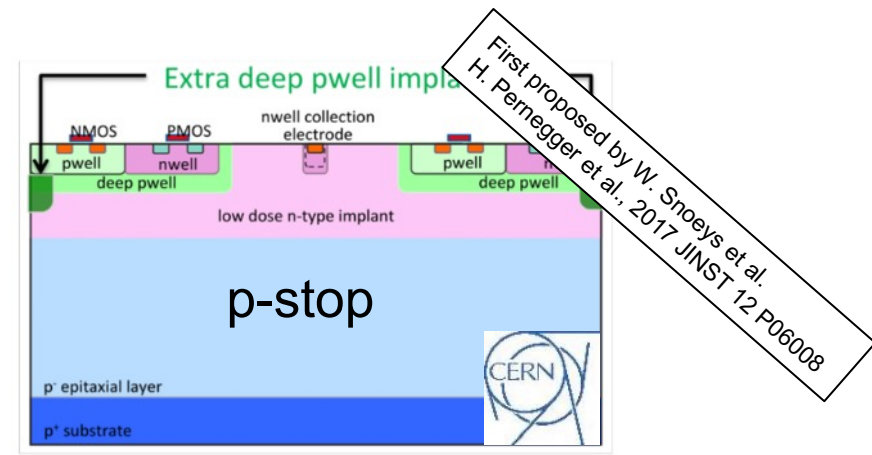


- Size: 504 x 1024 pixels (27x30 $\mu$ m<sup>2</sup>), 5 $\mu$ s time binning
- Full integrated: 20 MHz/cm<sup>2</sup> (80 MHz/cm<sup>2</sup> for 35 $\mu$ s), ~70mW/cm<sup>2</sup>
- Fully depleted: >20V top bias



Known from ALICE/ALPIDE

+ Radiation hardness  
- Spat. Resolution



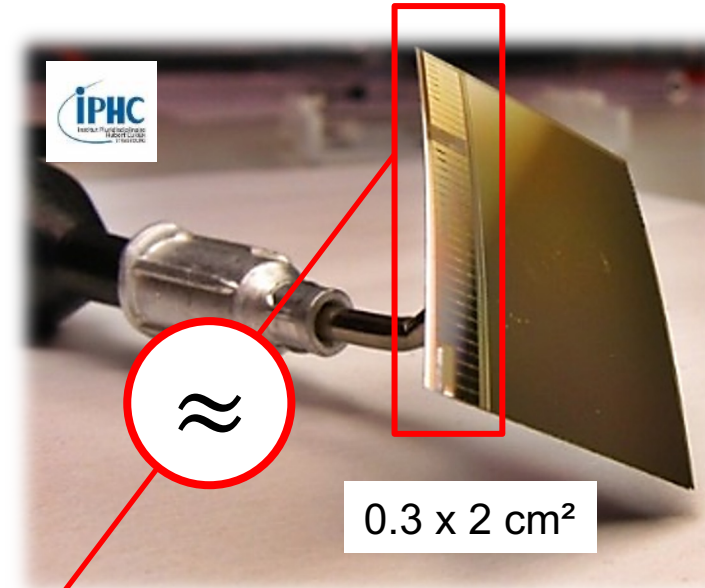
Rad. hard, candidate 1

Epitaxial layer thickness: 25 $\mu$ m, 50 $\mu$ m (new => reported today).

MIMOSIS integrates:

- Analog & Digital FEE
- Voltage regulators, trim DACs.
- Slow control interface.
- Data pre-processing.

...

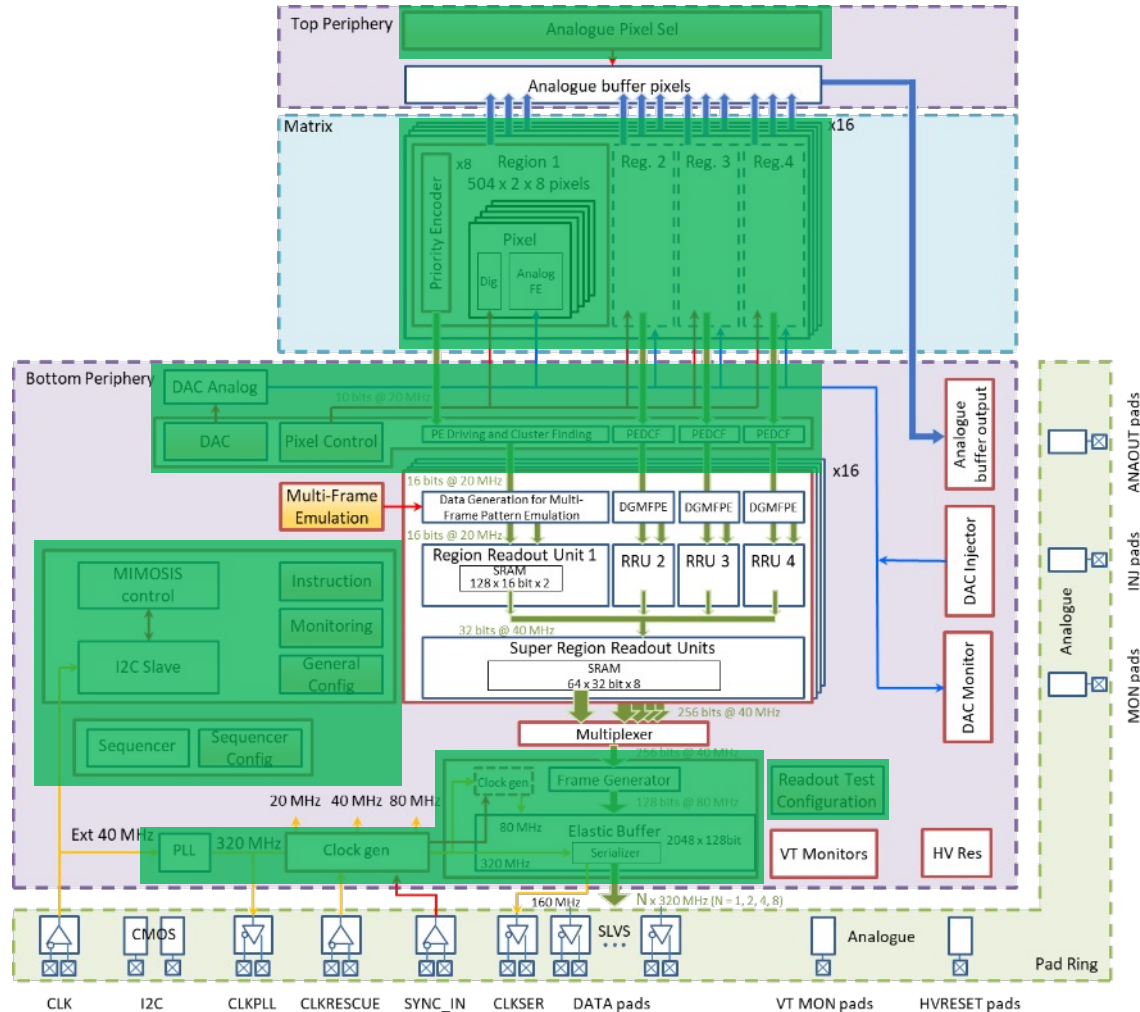


MIMOSIS is an unusually complex piece of technology, also during R&D.

# MIMOSIS-2 – what was changed?

## Reworked blocks in MIMOSIS-2

(F. Morel @ Mimosis sensor perspectives and next steps towards the CBM-MVD  
<https://indico.gsi.de/event/15130/>)

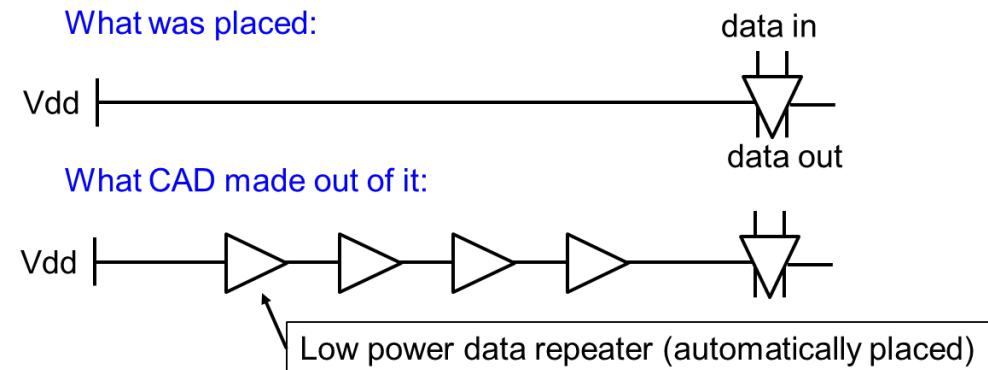


MIMOSIS-1 and MIMOSIS 2 follow the same outside specs but:

- Major features added.
- Majority of all blocks reworked.

⇒ High risk submission

Bug example: Output driver powering issue:



Status Sept. 2023:

- 3 bugs spotted, fixes under evaluation.
- Resubmission required for full bug fix.
- Updated test plans accounting for MSIS-2 limits.



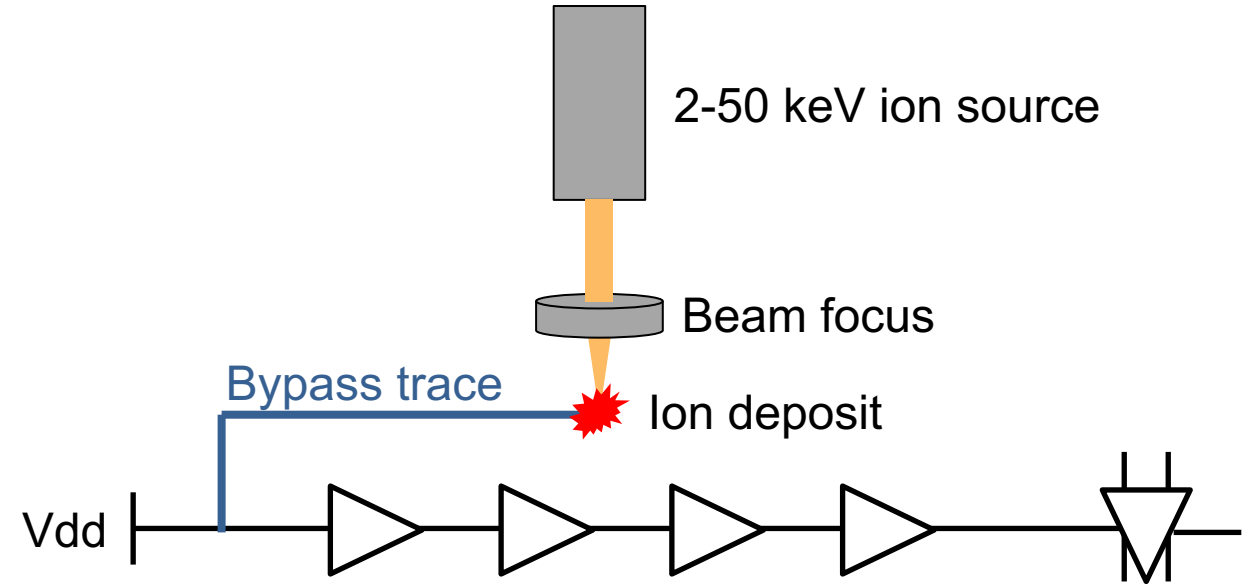
## Focused ion beam (FIB):

- Ion deposit in existing ASICs allows to add/cut traces.
- May be used to correct for bugs (equivalent to soldering cables on buggy PCB).

## Limitation:

- Space constraints.
- Individual ASICs only.

FIB used on 5 sensors to confirm bug repair strategy.



Sept 2023: “FIB corrected MIMOSIS-2 will plausibly allow to test a significant part of the open questions...”

Scheduled test	Test possible despite bugs?	Test result
Sensor performance	No	MIMOSIS-1 matches specs.
I2C issues (multiple)	Yes	OK
Analog output failure	Yes	OK (next talk)
Vulnerability to HV pickup	Yes	OK (next talk)
Vulnerability to HI-impacts	Yes	Q1-2 2024 (UNILAC beamtime)
Clk triplication	Restricted	So far ok.
PLL stability	After FIB	Improved, still too much jitter
Cluster finding	After FIB	OK
Pixel to output data transfer	After FIB	OK
Power grid (ohmic loss)	Restricted, after FIB	OK (but only few pixels)
...		

New

Validated bug fixing strategy.  
MIMOSIS 2.1 submitted Dec. 2023.

# Effect of heavy ion hits on electronics

Heavy ions show high  $dE/dx$  or LET:

- Scales with  $z^2$  of the projectile => Au = 6200 M.I.P
- Bethe Bloch: "Slow" ions create higher LET than relativistic ions.

Minority charge carriers excited by ions may:

- Break transistor gates => Gate rupture
- Switch digital electronics => Bit flip
- Open unwanted conduction paths => Latch-up (like short cut, extinguish by power cycle)

Irreversible destruction

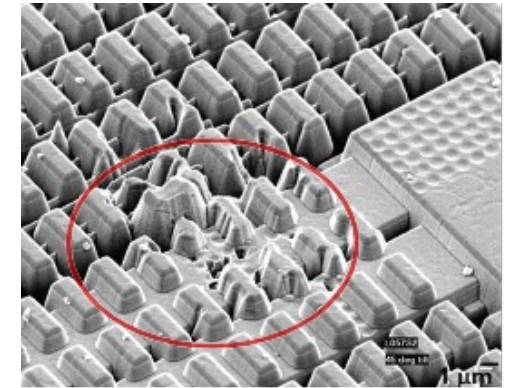
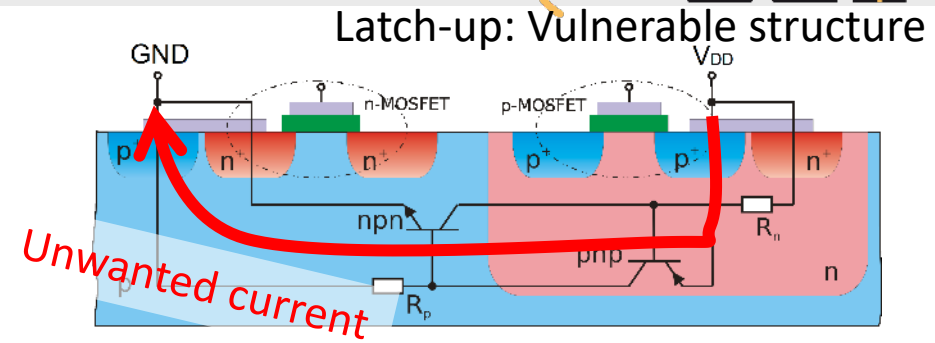
Malfunction if ignored

Thermal destruction if ignored

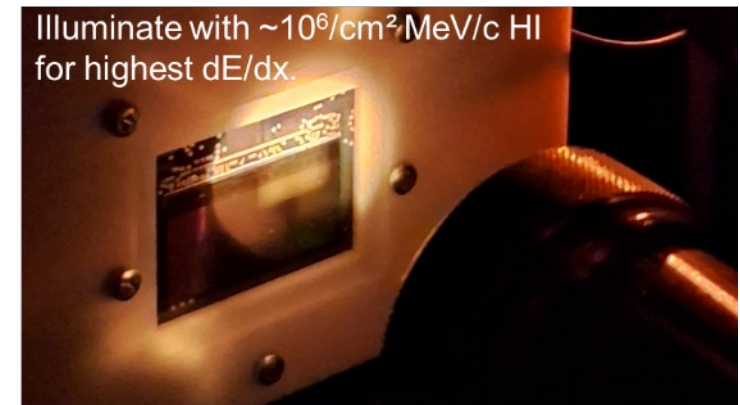
Macroscopic damage by individual ion: **Single Event Effect.**

Ways to spot SEE:

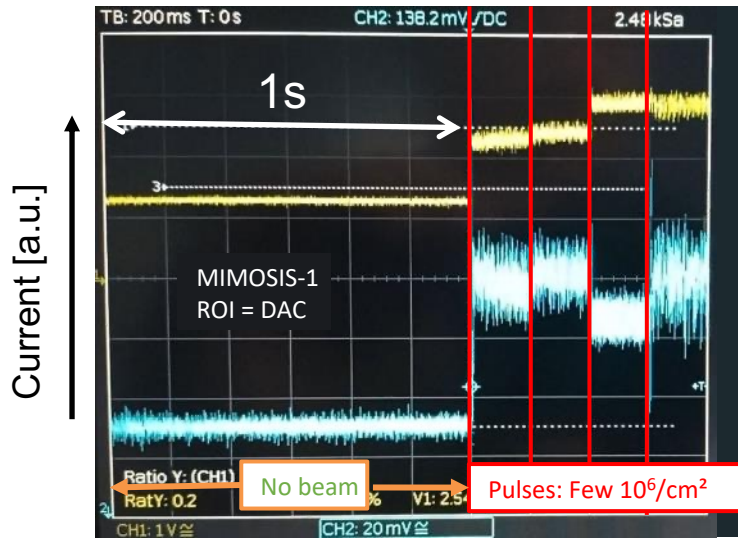
- Gate rupture: Search for permanent failure (not observed).
- Bit flip: Write register with known date, read back, compare.
- Latch-up: Detect increase of current consumption.



Latch-up in ULTIMATE sensor  
G. Contin, JINST 11 C12068 (2016)



## MIMOSIS-1:



Hits in DAC steering registers confuse sensor.

- 1-bit flip automatic recovery **does not work**.
- Need power cycle to restart.

No latch-up observed (for LET = 20 MeV cm<sup>2</sup>/mg). ✓

Sensor withstands 400 MHz/cm<sup>2</sup> HI (beam impact scenario) w/o damage. ✓

Single bit flip recovery circuits now working.  
=> Major improvement in robustness (as hoped).

## MIMOSIS-2:



Hits in DAC steering registers tolerated.

- 1-bit flip automatic recovery **does work**. ✓
- May be overwhelmed (2 sync bitflips).
  - Observed at fluences  $\sim 10^2$  above specs. ✓
  - Recovered by reprogramming (most of the time). ✓



## Requirement for MVD:

- Must withstand  $LET < 35 \text{ MeV cm}^2/\text{mg}$ .  
(H. Darwish, PhD under preparation)

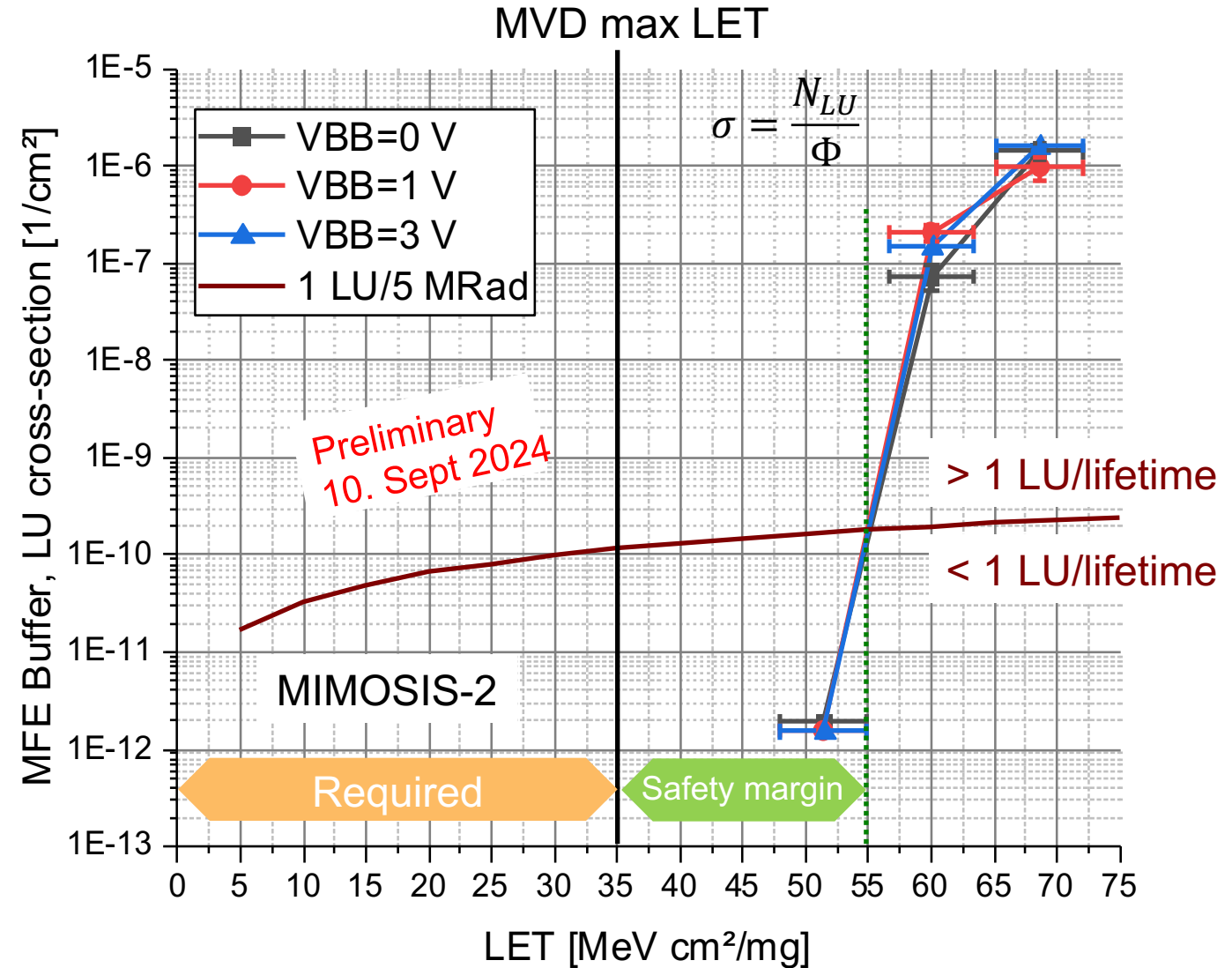
## Test with MIMOSIS-1:

- Withstands  $LET = 20 \text{ MeV cm}^2/\text{mg}$ .
- Limitation:  $dE/dx$  of Ca-ions used

## Test with MIMOSIS-2 (Au ions):

- No LU for  $LET \lesssim 50 \text{ MeV cm}^2/\text{mg}$ .
  - Some LU seen above.
- => MIMOSIS-2 meets requirements

Protection system for Latch-up  
(1 fast electronic fuse/sensor)  
likely not required.



Date	Event
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**P**repare MIMOSIS-2 re-submission => MIMOSIS 2.1

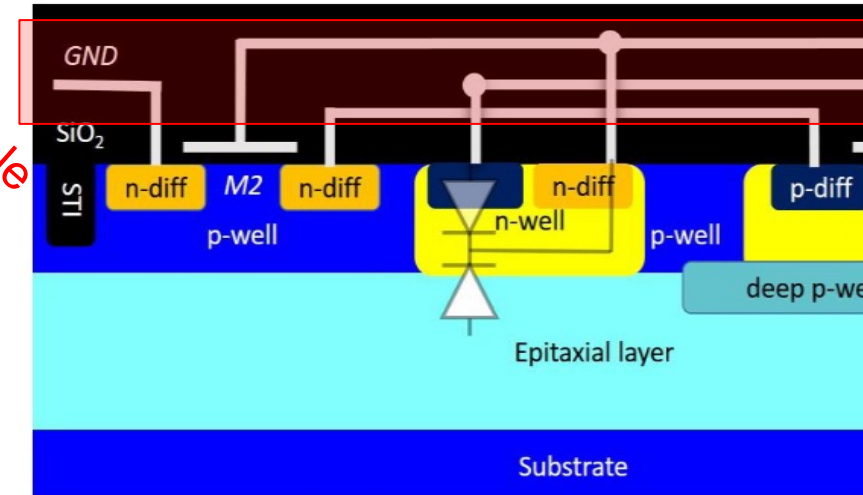
**S**trategy: Modify only few masks out of ~30 to save costs.

- few 100 kEUR saving (needed to finance MIMOSIS-3).
- may re-wire transistors but not move/replace them.  
⇒ Some issues (PLL) cannot be addressed.

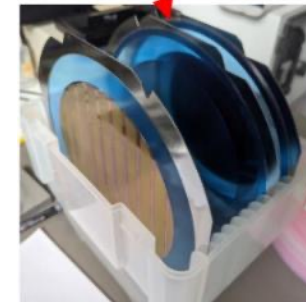
**E**xpect working sensor requiring external 320 MHz clk.

**P**aid extra fee for fast processing.

*reworkable*



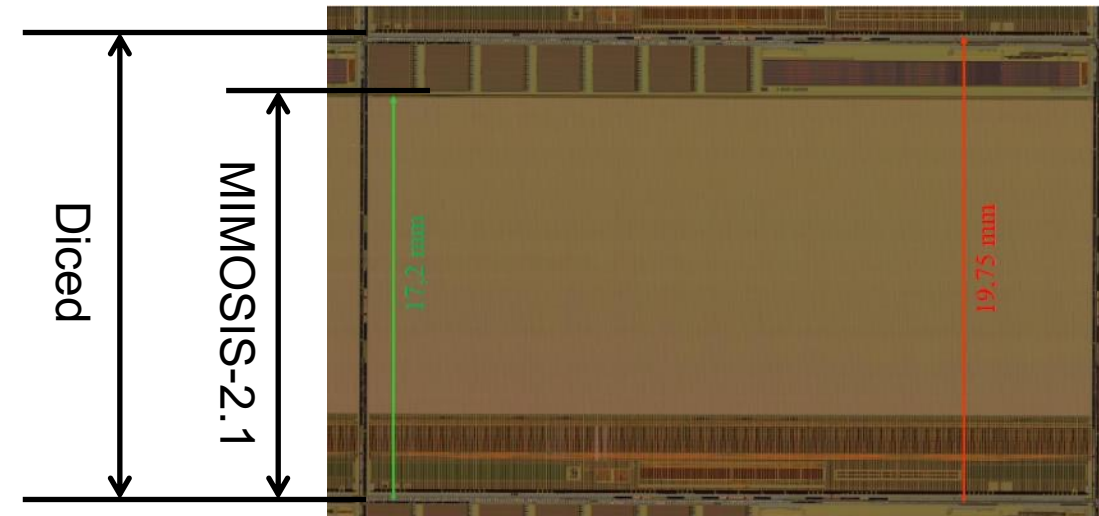
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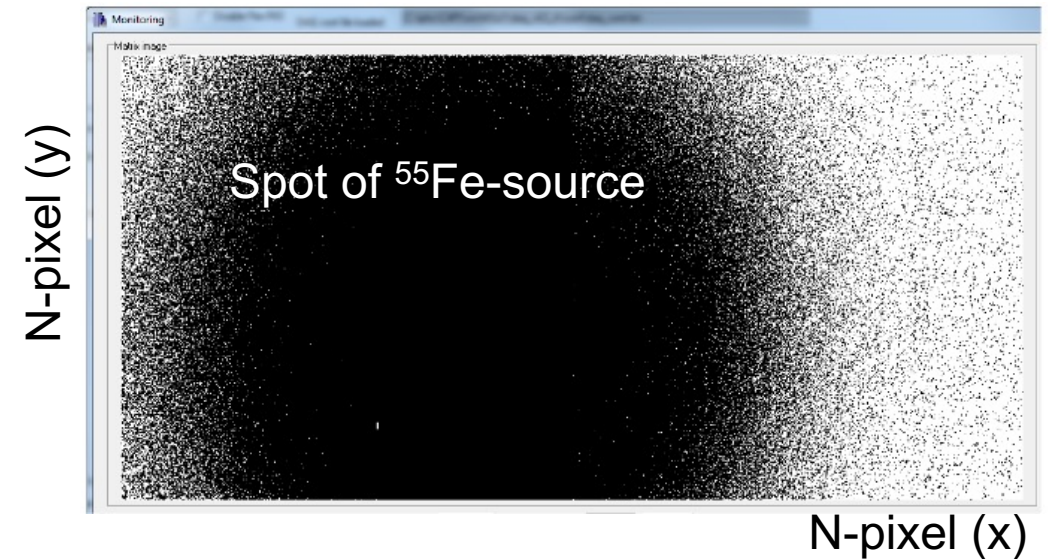
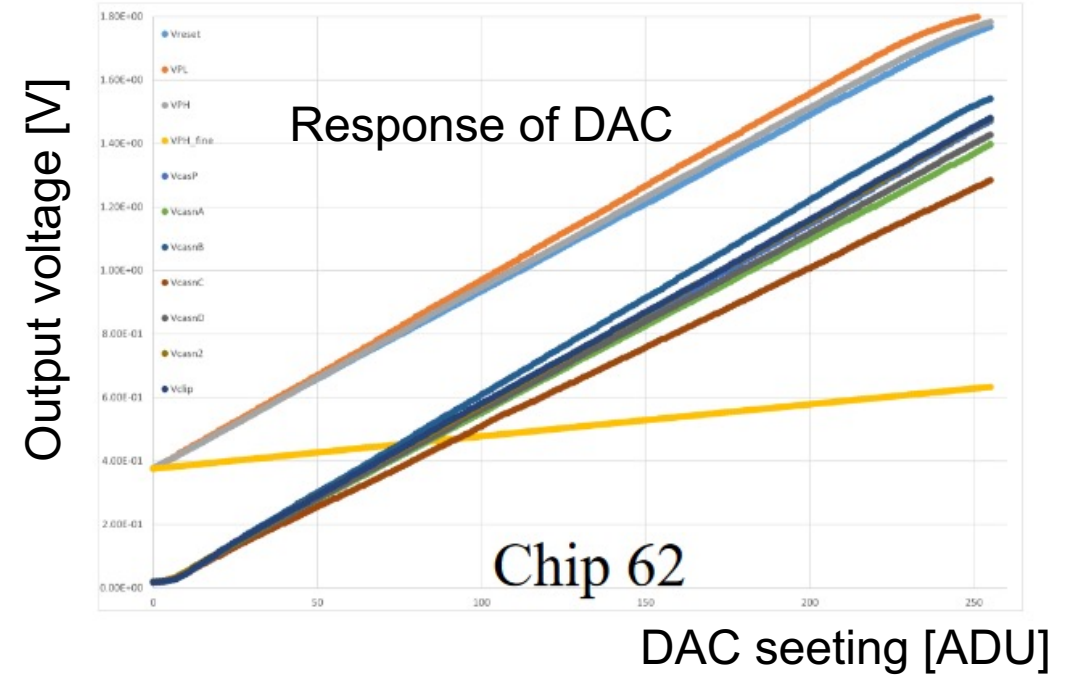
4 diced wafers (one of each split) &



8 full wafers



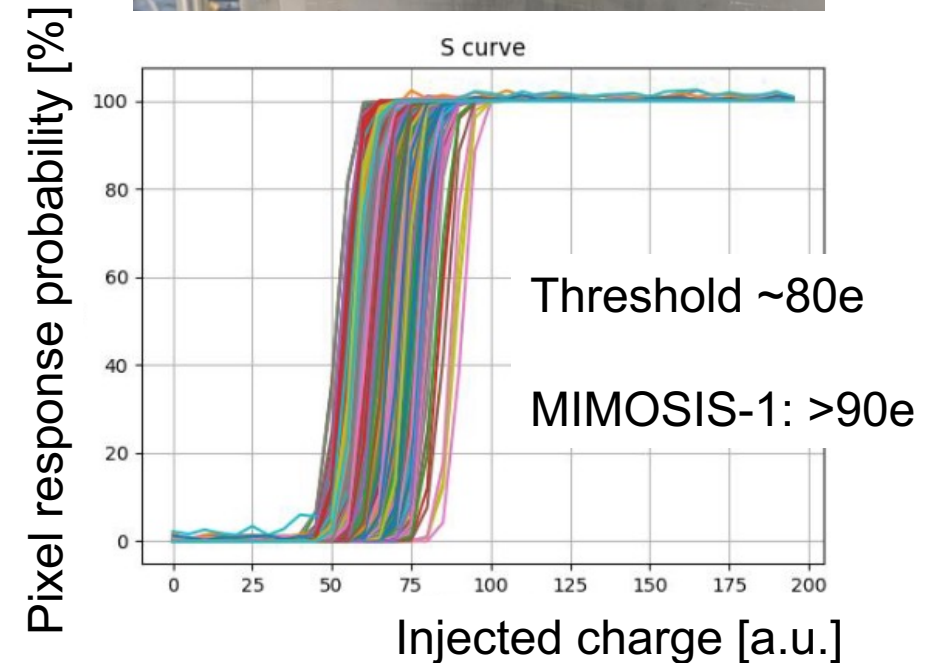
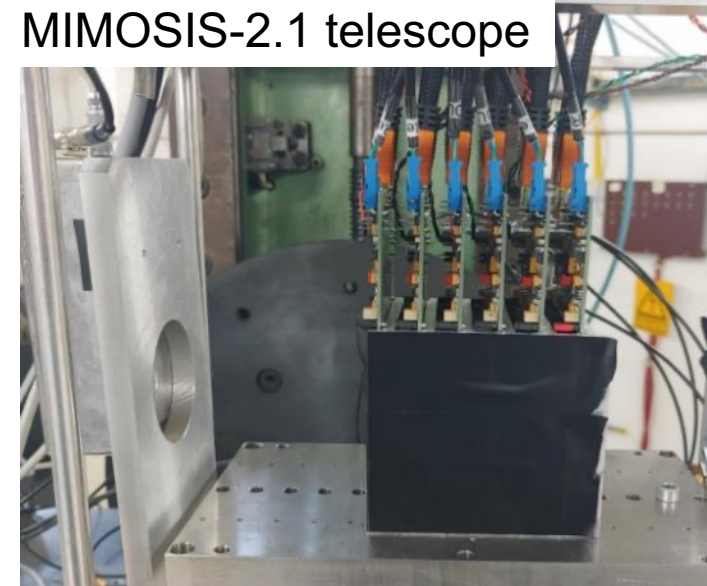
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MIMOSIS-2.1 telescope



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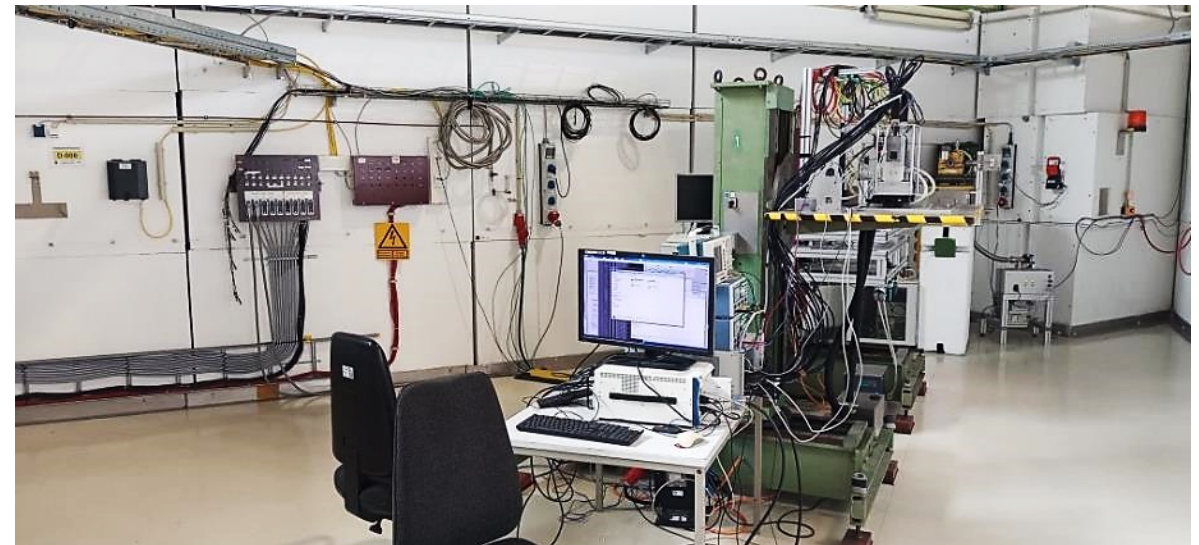


Shopping of last items



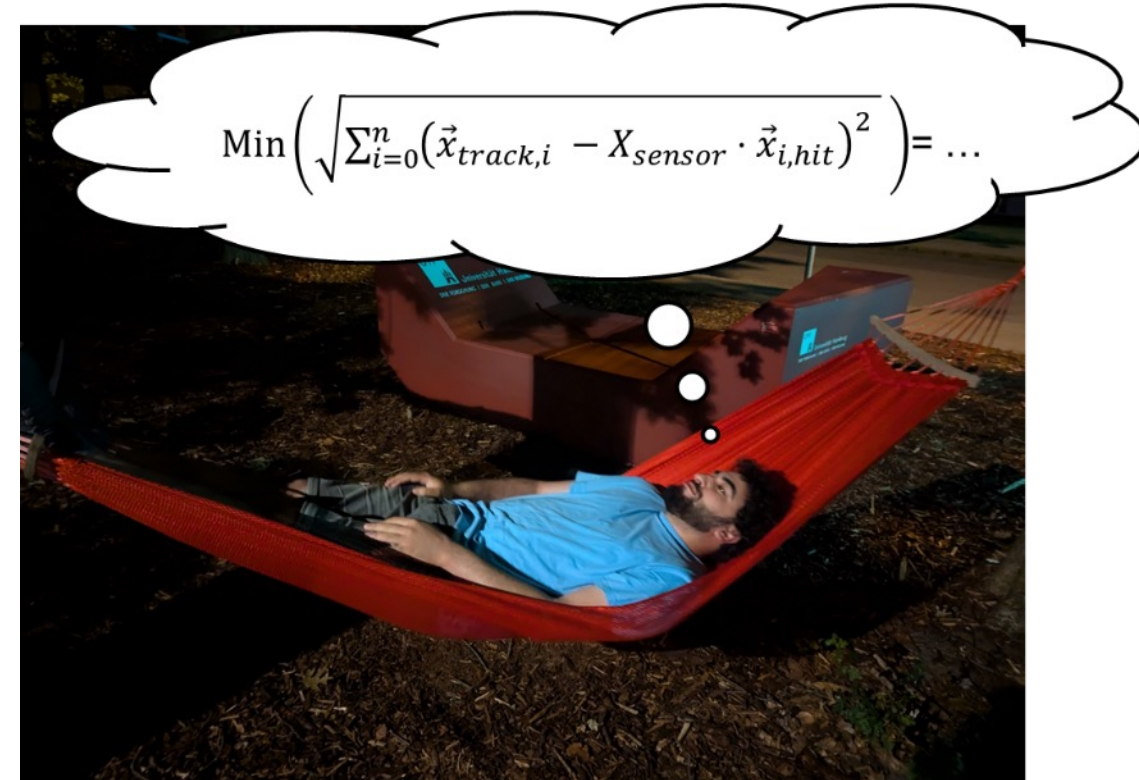
Arrival at DESY

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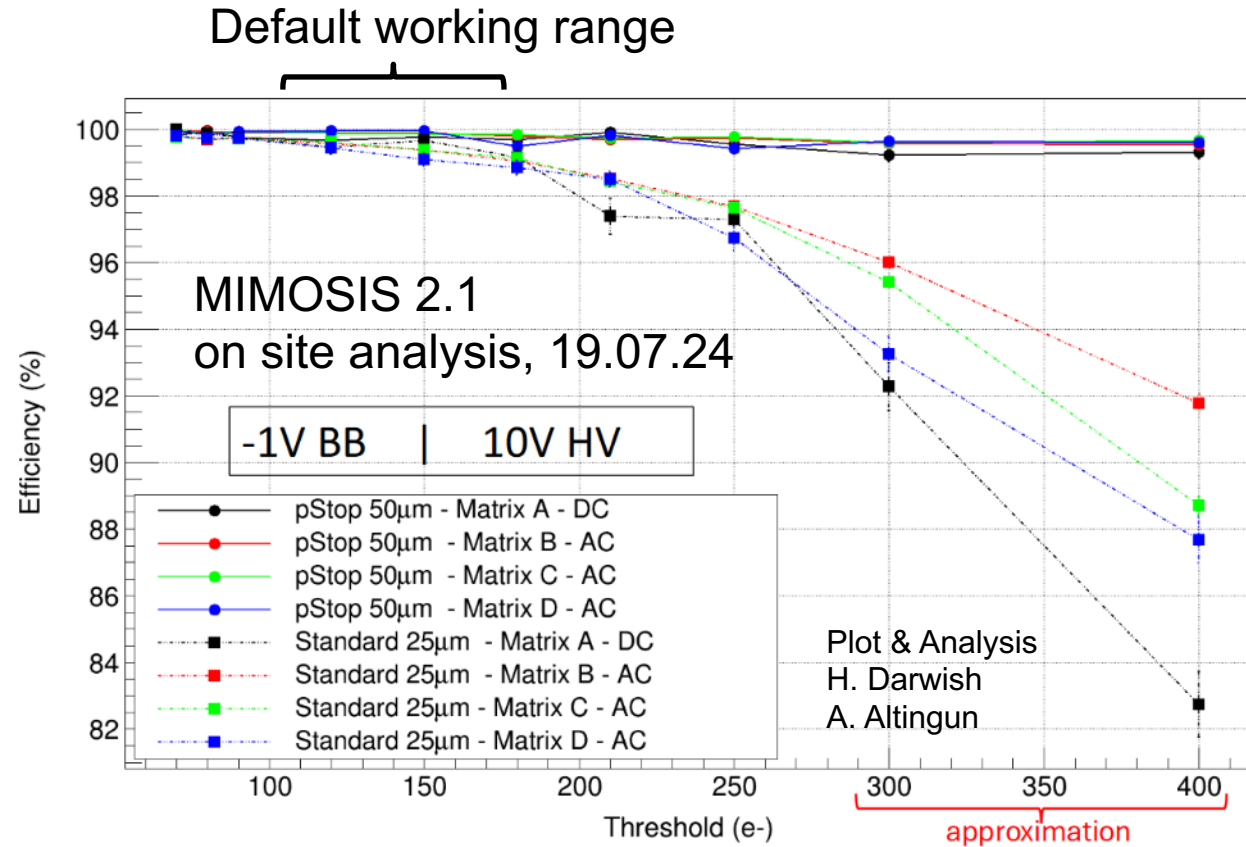




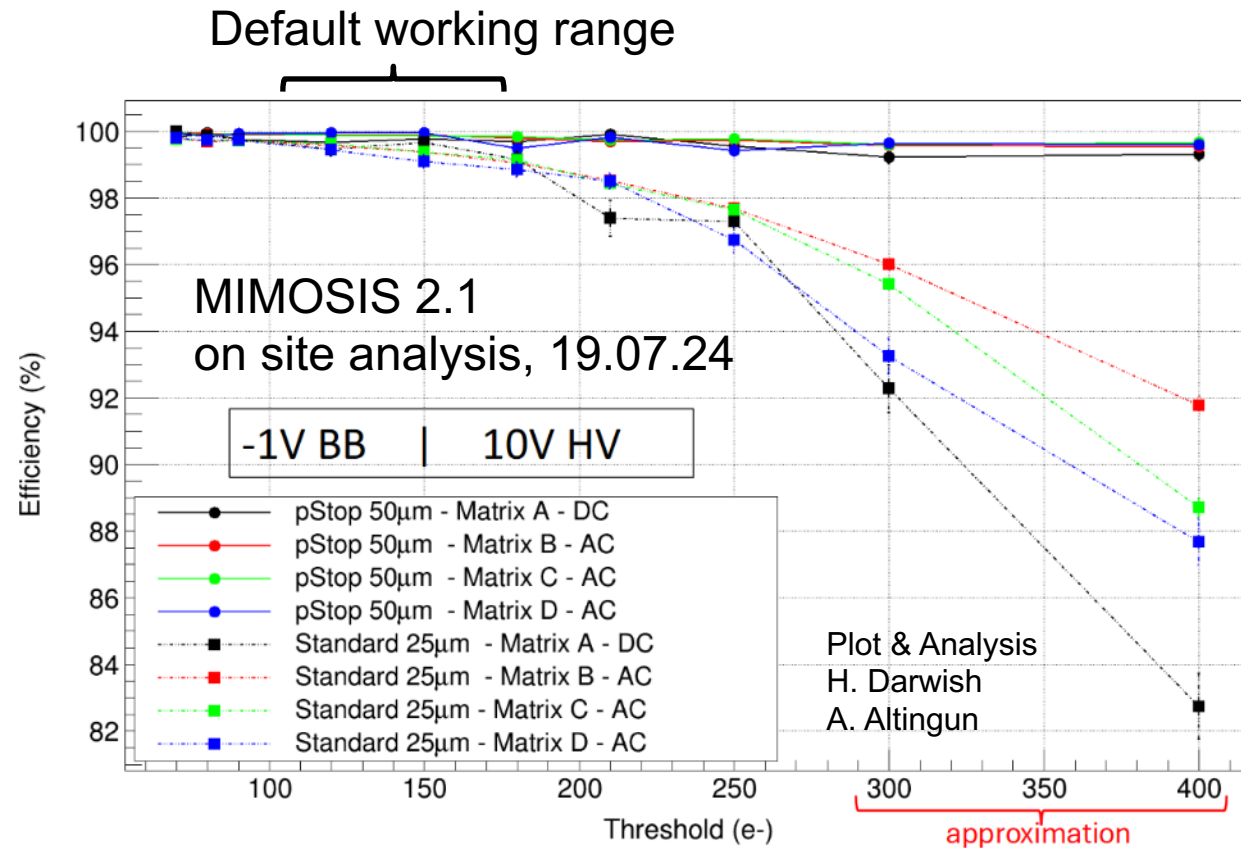
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19.07.2024	Beam test results shown in regular Friday meeting. →

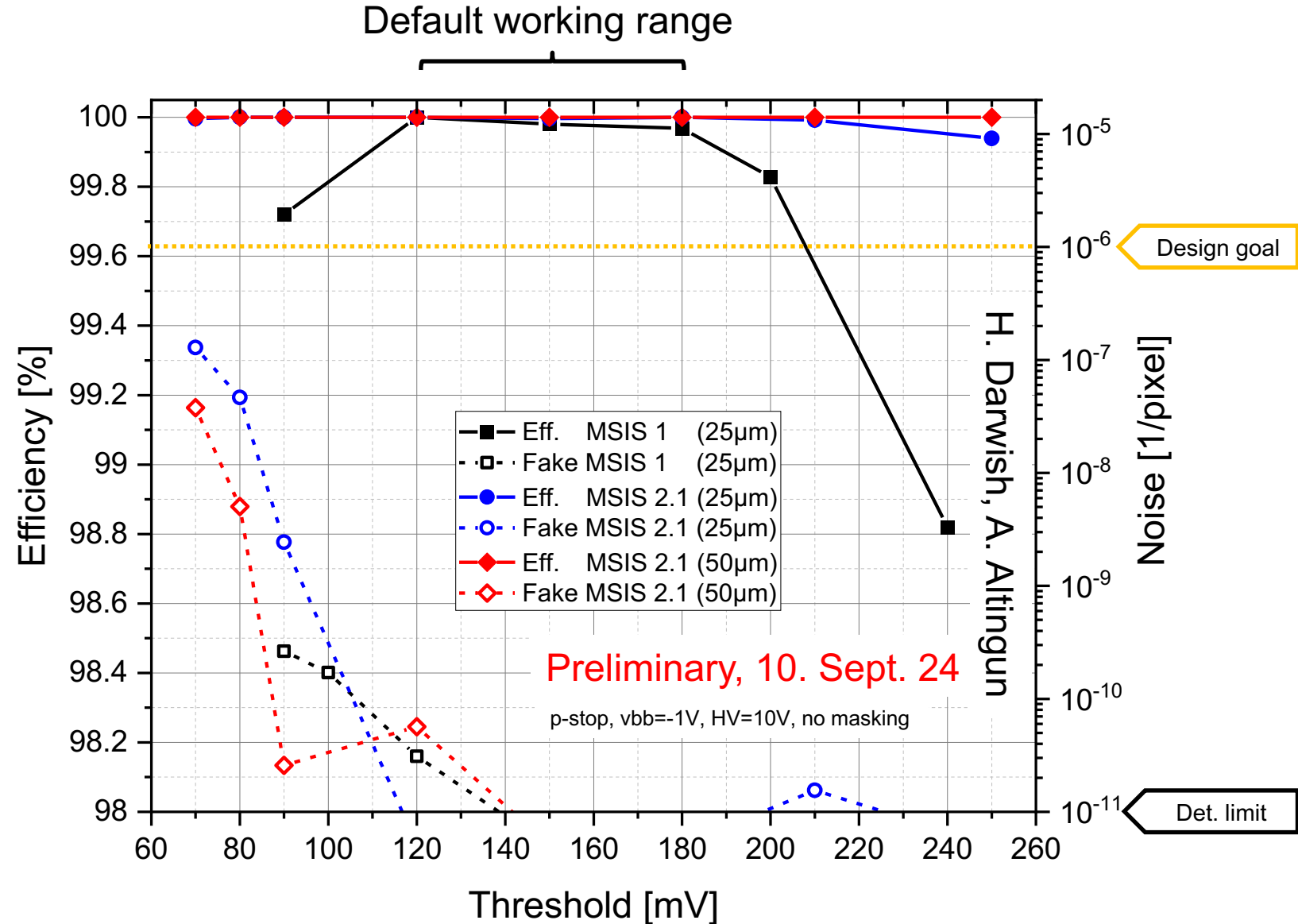


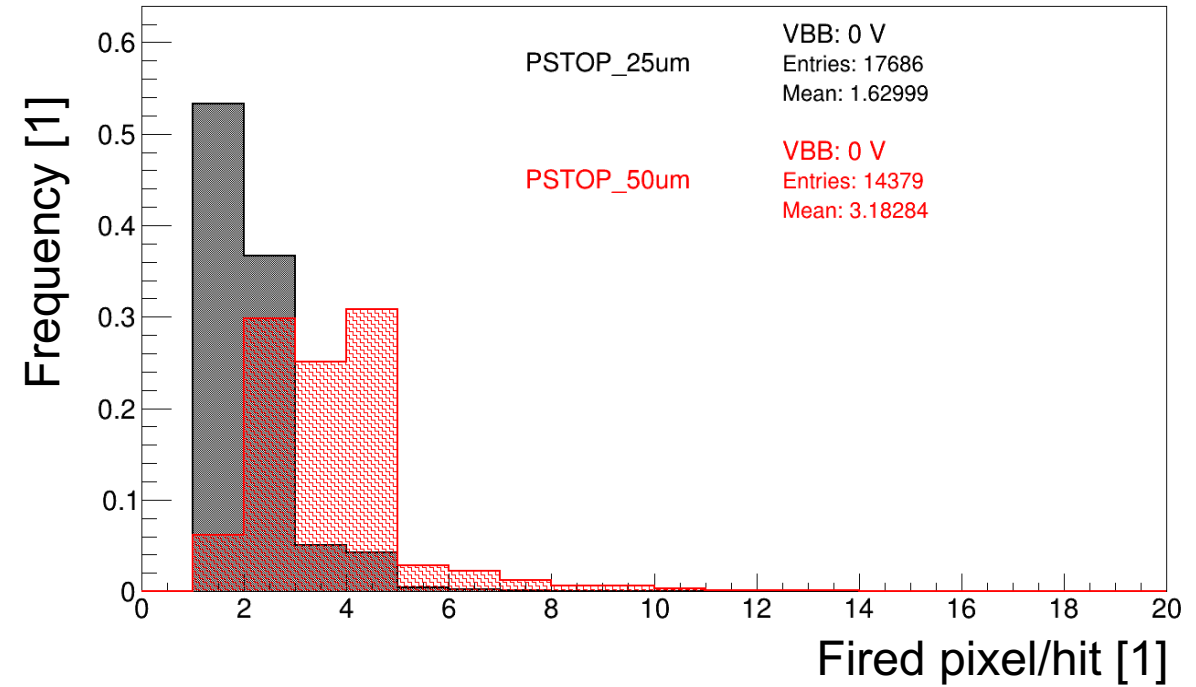
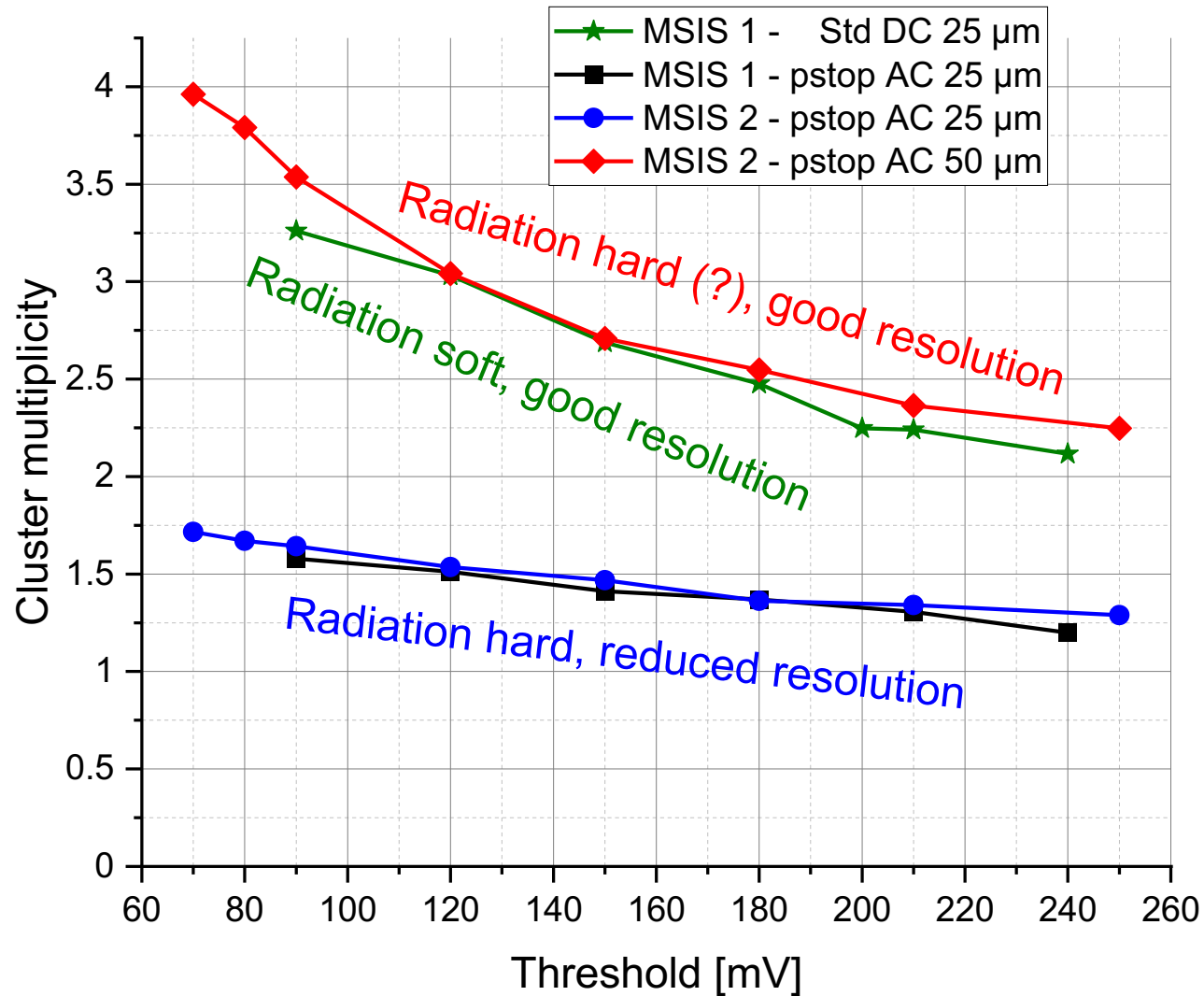
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19.07.2024	Beam test results shown in regular Friday meeting. →
26.08.2024	First preliminary analysis: 50 slides of plots.



## Observations:

- MIMOSIS-2.1 reaches lower threshold than MIMOSIS-1.
- MIMOSIS-2.1 reaches even(!) higher efficiency than MiSIS-1.
- Best performance: Novel 50 $\mu$ m epitaxial layer with p-stop.
- Dark occupancy marginal for all sensors (noisy pixels NOT masked).





Observation:

⇒ MIMOSIS-2.1 p-stop 50 $\mu\text{m}$  combines high cluster multiplicity with rad. tolerant structure.

Might yield best combination of spatial resolution and radiation tolerance (rad tolerance t.b.c).

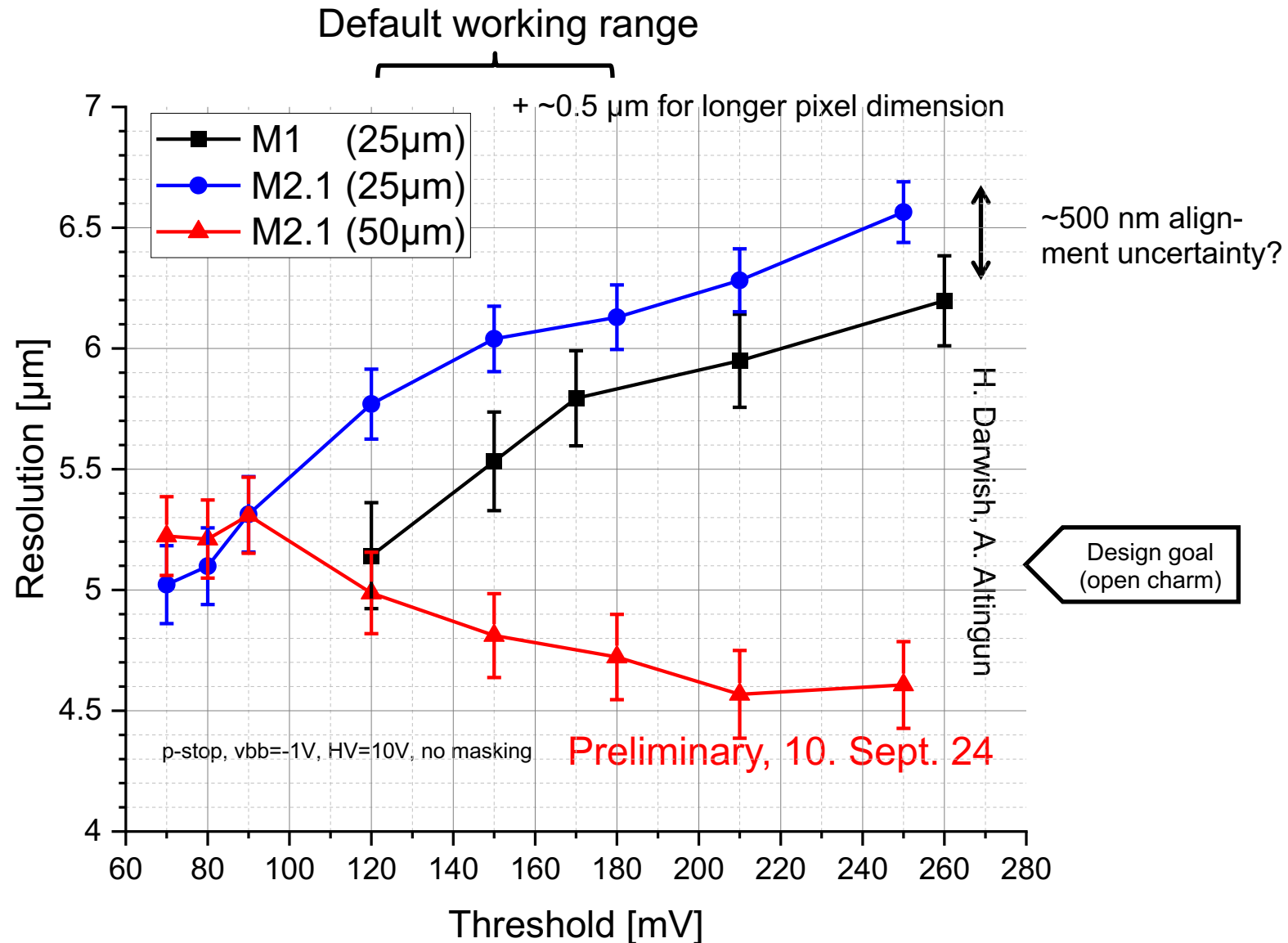


## Observations:

- MIMOSIS-2.1 and MIMOSIS-1 show mostly same resolution for 25  $\mu\text{m}$  (expected, discrepancy to be studied).
- MIMOSIS-2.1 50  $\mu\text{m}$  reaches better resolution (as hoped).

## Preliminary conclusion:

- Novel 50  $\mu\text{m}$  p-stop appears most promising.
- Need to study radiation tolerance before concluding.



## MIMOSIS 2.1 works as expected (so far):

- Novel 50 $\mu$ m p-stop sensor shows further improved performance.
  - Full readout chain validated.
  - Tolerance to SEE now established (gate rupture, Latch-up, slow control).
- ⇒ Sensor fulfills requirements

## Open ends:

- Internal PLL still not fixed.
  - Expert review planned for Q4/2024.
  - Worst case: May have to distribute 320 MHz clk.
- Yield not satisfactory – under study with tools available since 2024.
  - Worst case: Additional money and effort to buy/test more wafers.
- Impact of SEE on data taking not yet rigorously excluded – Need beam test.

## Next steps:

- Beam tests (starting this week, Q1/2025) to understand sensors better.
- Participation to mCBM (test in real environment).
- Test with realistic LV-distribution.

## MIMOSIS R&D back on track.

Program in schedule (presented at ECE in Apr. 2024).

Expect MIMOSIS-3 (final sensor) by end 2025.

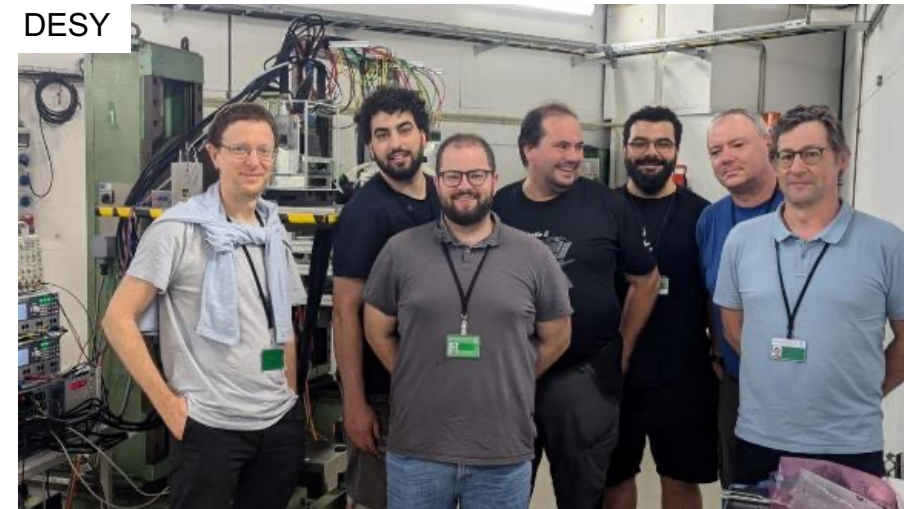
## Test team:

UNILAC



M. Dx Ben Kay O. Benedikt Oliver  
Arnoldi Voss Gutsche Keller

DESY



Auguste Hasan Mathieu Ali Al-  
Besson Darwish Goffe tingun Specht

...Julio Andary, Gilles Claus, Kimmo Jaaskelainen...

# News from CE65

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A. Dorokhov<sup>d</sup> Z. El Bitar<sup>d</sup> M. Goffe<sup>d</sup> T. Gunji<sup>c</sup> C. Hu-Guo<sup>d</sup> A. Ilg<sup>b</sup> K. Jaaskelainen<sup>d</sup> T.  
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J. Park<sup>e</sup> S. Sakai<sup>e</sup> S. Senyukov<sup>d</sup> H. Shamas<sup>d</sup> D. Shibata<sup>e</sup> W. Snoeys<sup>g</sup> P. Stanek<sup>h</sup> M.  
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<sup>b</sup>University of Zurich, 8057 Zurich, Switzerland

<sup>c</sup>University of Tokyo, Tokyo 113-8654, Japan

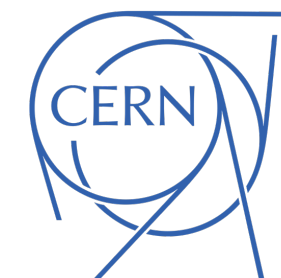
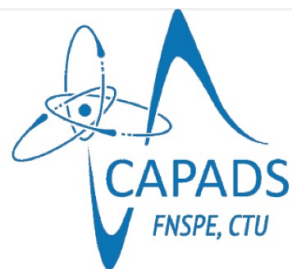
<sup>d</sup>Université de Strasbourg, CNRS, IPHC UMR 7178, F-67000 Strasbourg, France

<sup>e</sup>University of Tsukuba, Tsukuba, Ibaraki 305-8577, Japan

<sup>f</sup>Hiroshima University, Higashi-Hiroshima 739-8526, Japan

<sup>g</sup>CERN, CH-1211 Geneva 23, Switzerland

<sup>h</sup>Czech Technical University in Prague, 160 00 Prague, Czech Republic



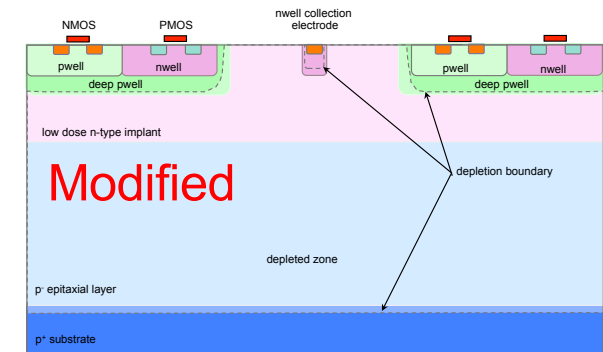
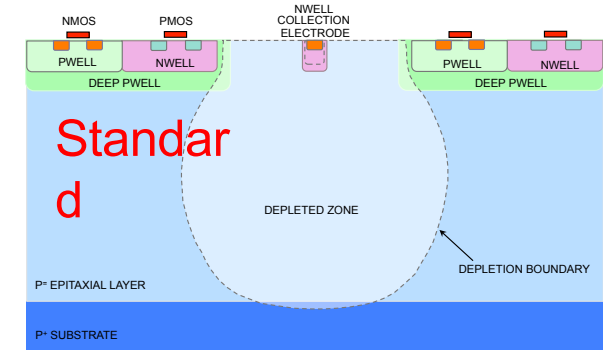
筑波大学  
University of Tsukuba



ALICE

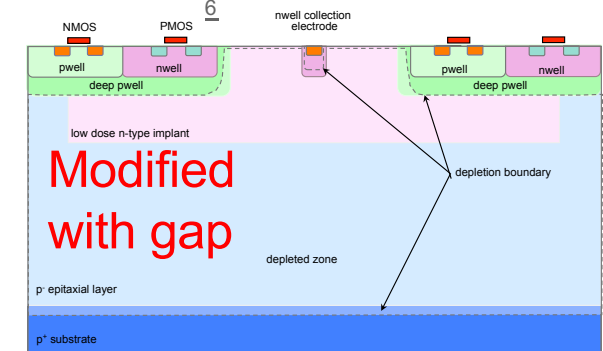


- **Benefits: 65 nm vs 180 nm**
  - Better spatial resolution due to smaller feature size
  - Larger wafers: 300 mm vs 200 mm => final sensor: 27x9 cm<sup>2</sup>
  - Lower power supply: 1.2 V vs 1.8 V => Low power consumption
  - Lower material budget: thinner sensitive layer (~ 10  $\mu\text{m}$ )
- Provides 2D stitching
- 7 metal layers
- **Process modifications for full depletion:**
  - Standard (no modifications)
  - Modified (low dose n-type implant)
  - Modified with gap (low dose n-type implant with gaps)



<https://doi.org/10.1016/j.nima.2017.07.04>

6

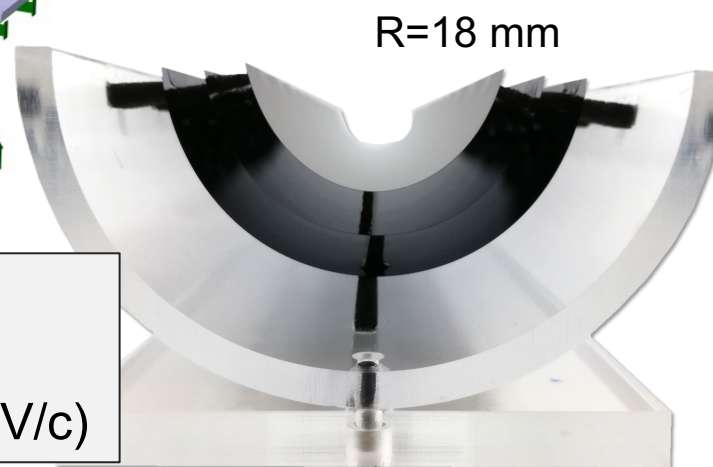
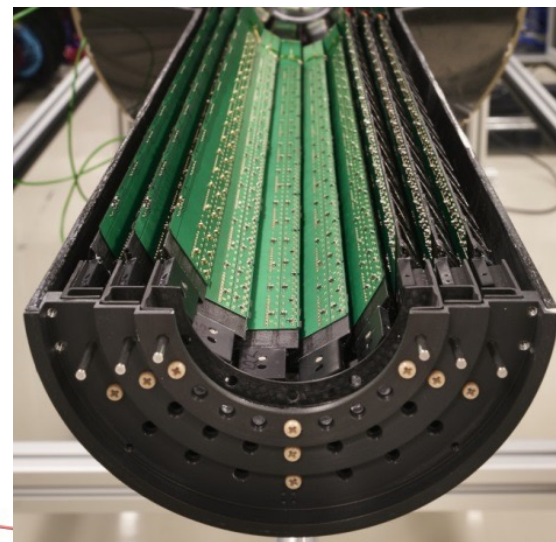
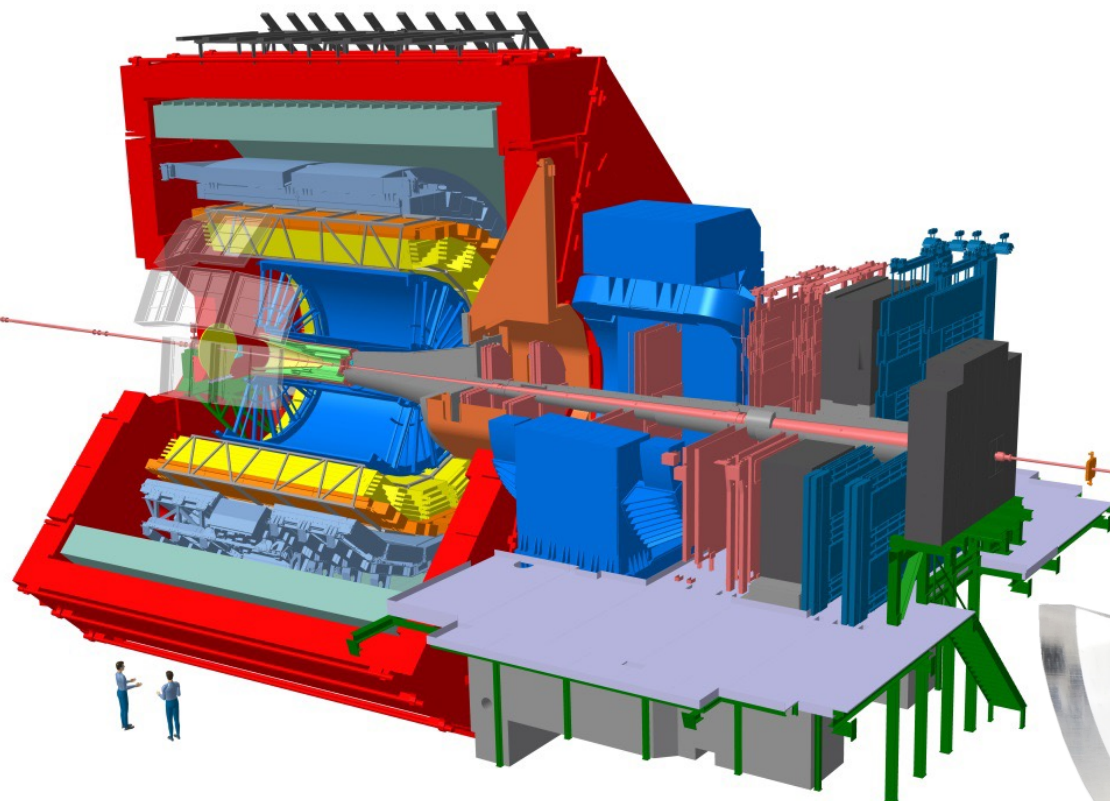


<https://iopscience.iop.org/article/10.1088/1748-0221/14/05/C05013>



# ALICE DETECTOR LS3 UPGRADE: ITS2 (180 nm) → ITS3 (65 nm)

R. Ricci, PSD 2023



ALICE – general purpose detector at LHC:

- Tracking (100 MeV/c – 100 GeV/c)
- Particle identification:  $\pi$ , K, p, e (0.1 – 50 GeV/c)

## ITS2:

(S.Beolé, iWoRiD 2022)

- 7 layers of MAPS
- TJ 180 nm CMOS
- 12.5 Giga pixels
- Pixel size:  $27 \times 29\ \mu\text{m}^2$
- Water cooling
- **0.3 %  $X_0$  / inner layer**

## ITS3

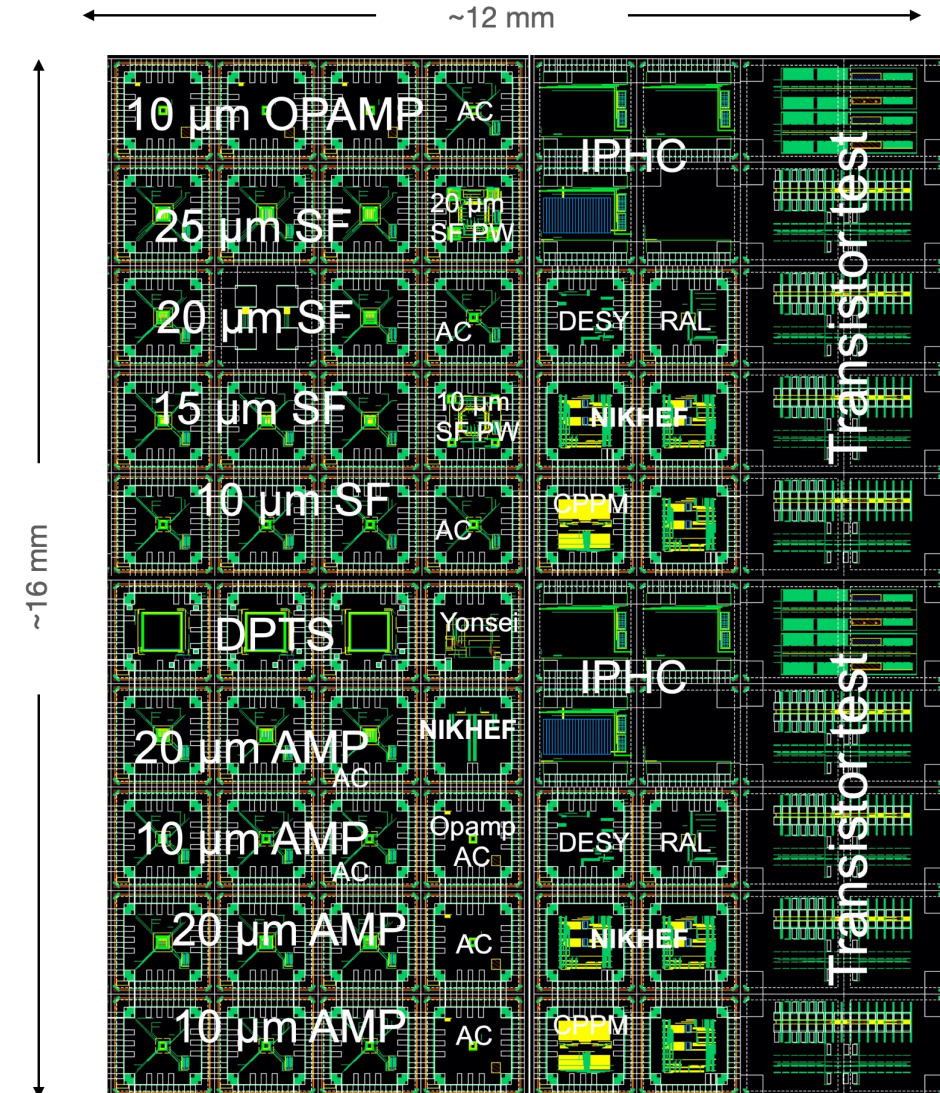
(M. Šuljić, iWoRiD 2023)

- 4 outer layers of ITS2
- 3 new fully cylindrical inner layers
  - Sensor size up to  $27 \times 9\text{ cm}$
  - Thickness  $\leq 50\ \mu\text{m}$
  - No FPCs
  - Air cooling in active area
- **0.05 %  $X_0$  / inner layer**

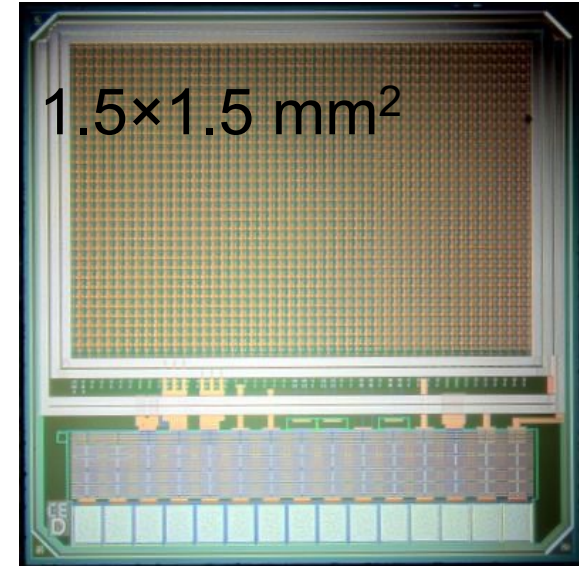
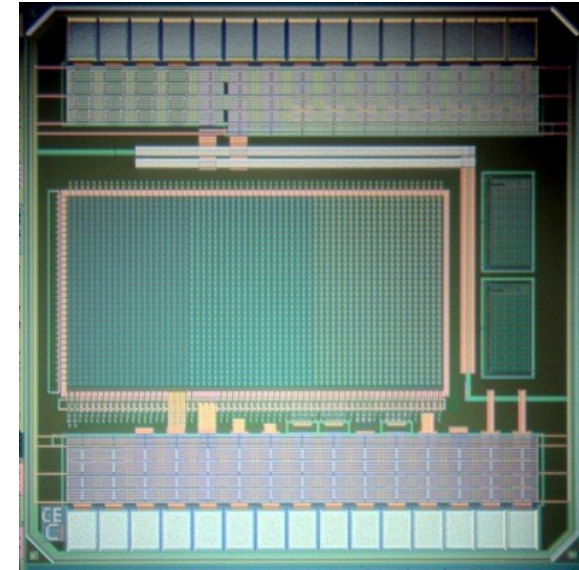


# First test submission : MLR1

- Submitted in December 2020
- Main goals:
  - Learn technology features
  - Characterize charge collection
  - Validate radiation tolerance
- Each reticle ( $12 \times 16 \text{ mm}^2$ ):
  - 10 transistor test structures ( $3 \times 1.5 \text{ mm}^2$ )
  - 60 chips ( $1.5 \times 1.5 \text{ mm}^2$ )
    - Analogue blocks
    - Digital blocks
    - **Pixel prototype chips: APTS, CE65, DPTS**



- 2 matrix sizes
  - 64×32 with 15  $\mu\text{m}$  pitch
  - 48×32 matrix with 25  $\mu\text{m}$  pitch
- Rolling shutter readout (50  $\mu\text{s}$  integration time)
- 3 in-pixel architectures:
  - AC-coupled amplifier
  - DC-coupled amplifier
  - Source follower
- 4 chip variants:
  - **Standard process 15  $\mu\text{m}$  pitch**
  - Modified process 15  $\mu\text{m}$  pitch
  - **Modified process with gaps 15  $\mu\text{m}$  pitch**
  - Standard process 25  $\mu\text{m}$  pitch
- Fabrication in September 2021
- Presented results from CERN PS beam test : May 2022



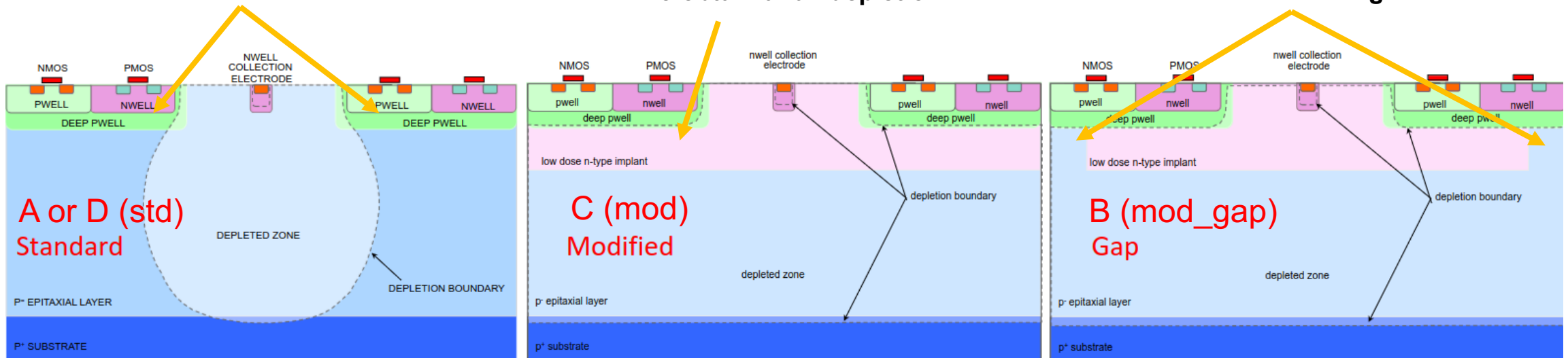
# CE-65 nm variants: pixel pitch and process

Variant	Process	Pitch	Matrix	Sub-matrix
CE65-A	std	15 $\mu$ m	64 $\times$ 32	AC/21, DC/21, SF/22
CE65-B	mod_gap	15 $\mu$ m	64 $\times$ 32	AC/21, DC/21, SF/22
CE65-C	mod	15 $\mu$ m	64 $\times$ 32	AC/21, DC/21, SF/22
CE65-D	std	25 $\mu$ m	48 $\times$ 32	AC/16, DC/16, SF/16

Prevent circuitry's nwells from collecting charge

To obtain a full depletion

To overcome the weak electric field near the edges





# Beam Test Setup

## Telescope:

Reference Arms : 4 ALPIDE planes for track reconstruction

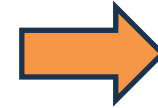
DUT : CE65  
TRG : DPTS

## Test beam:

May 2022 at CERN-PS

Support provided by Alice Collaboration

4 frames for each event



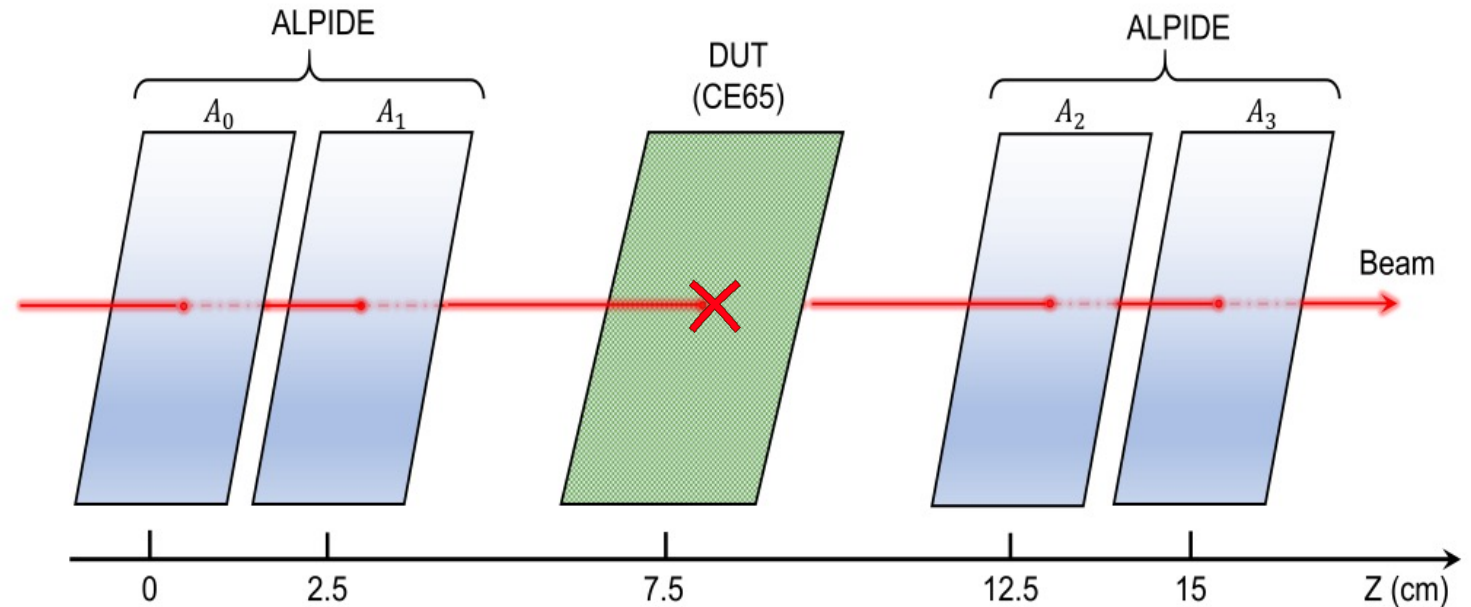
Pedestal map  
Noise map

Calibration file

Data acquisition:  
**EUDAQ2**

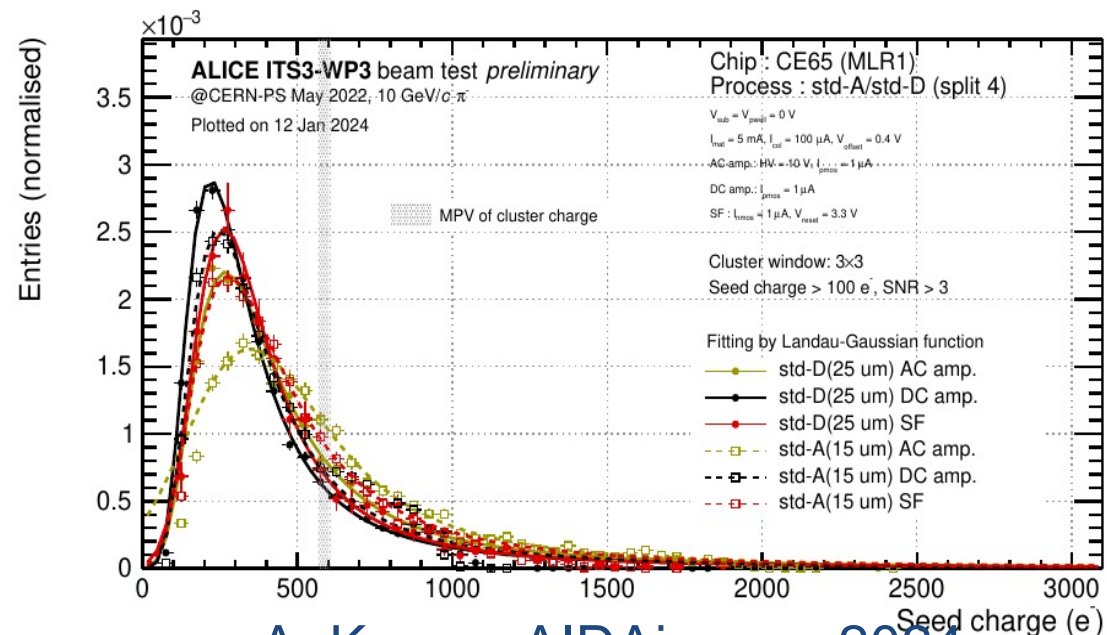
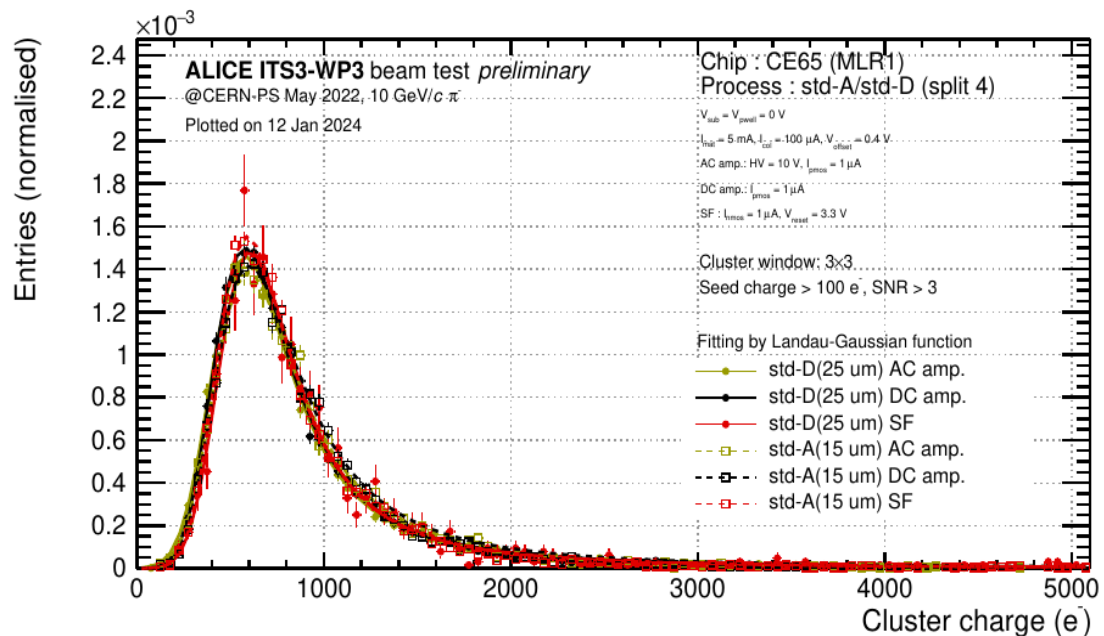
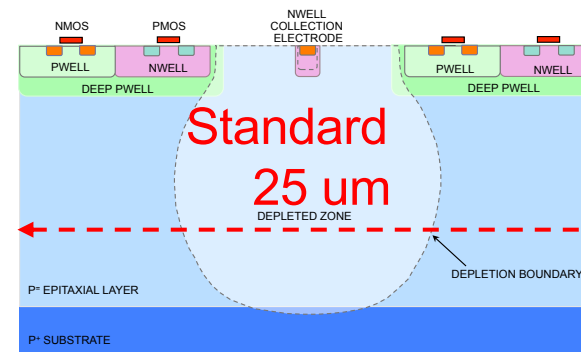
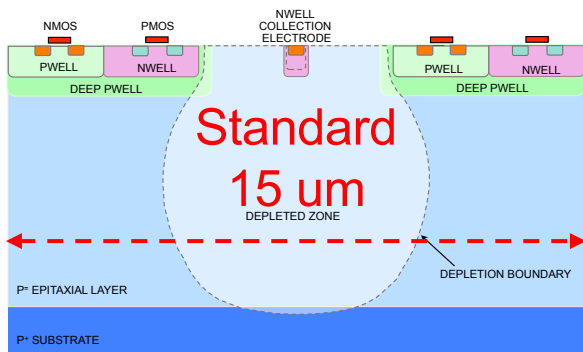
Event reconstruction  
algorithm and data analysis  
framework:  
**Corryvreckan**

**Noise run-Beam run:**  
correlated double sampling  
method (**CDS**)



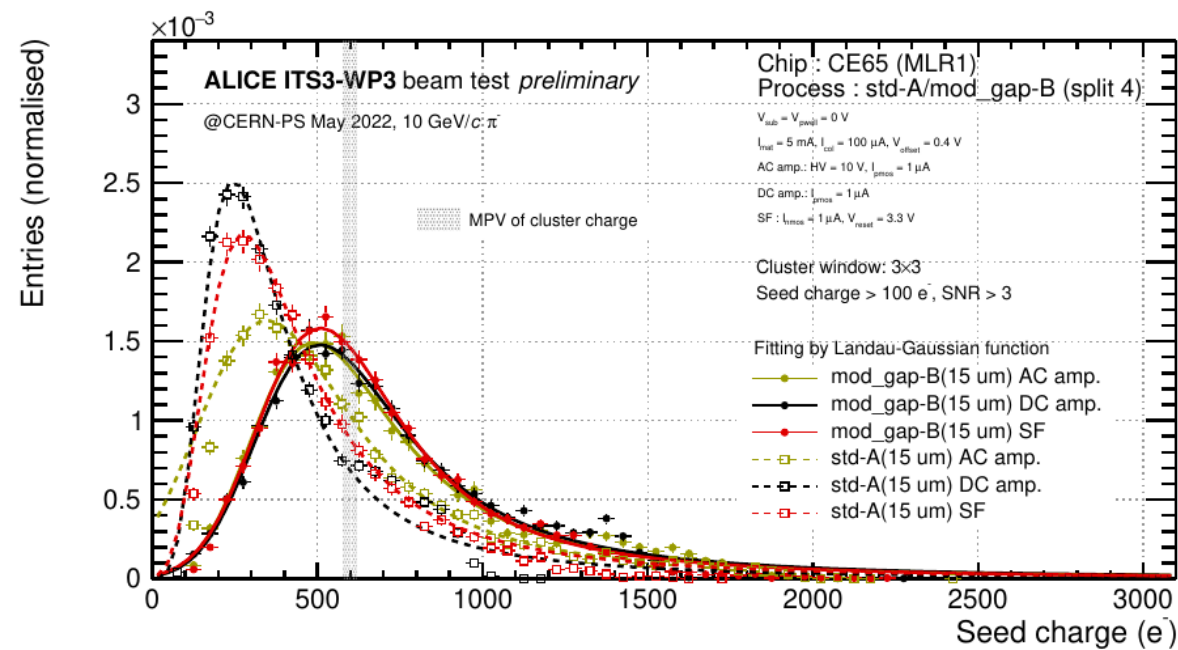
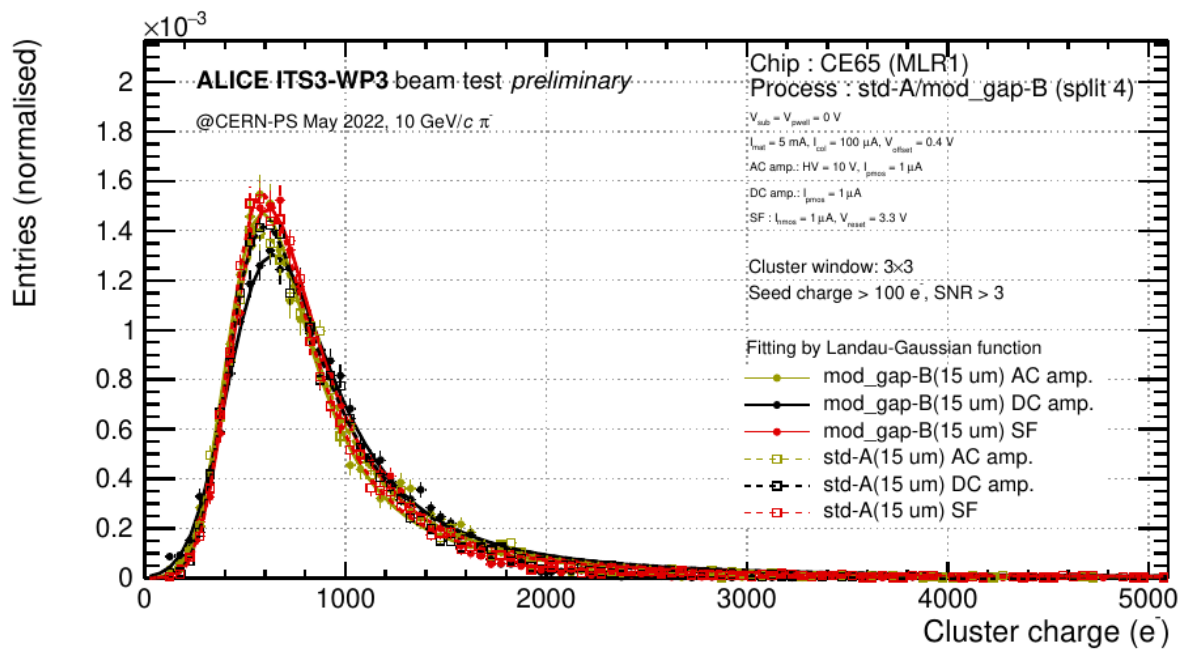
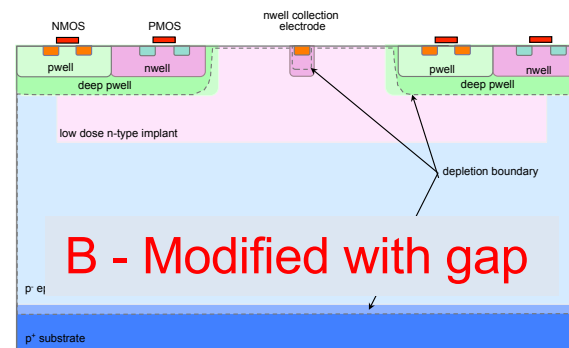
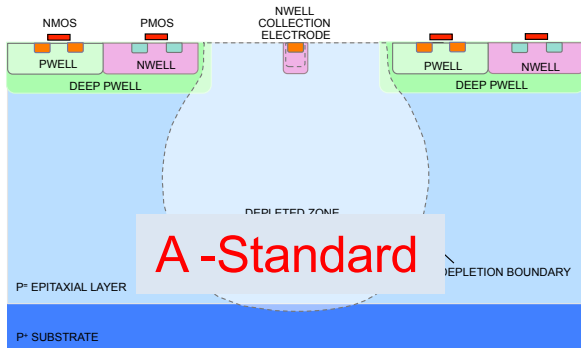


# Pixel size impact

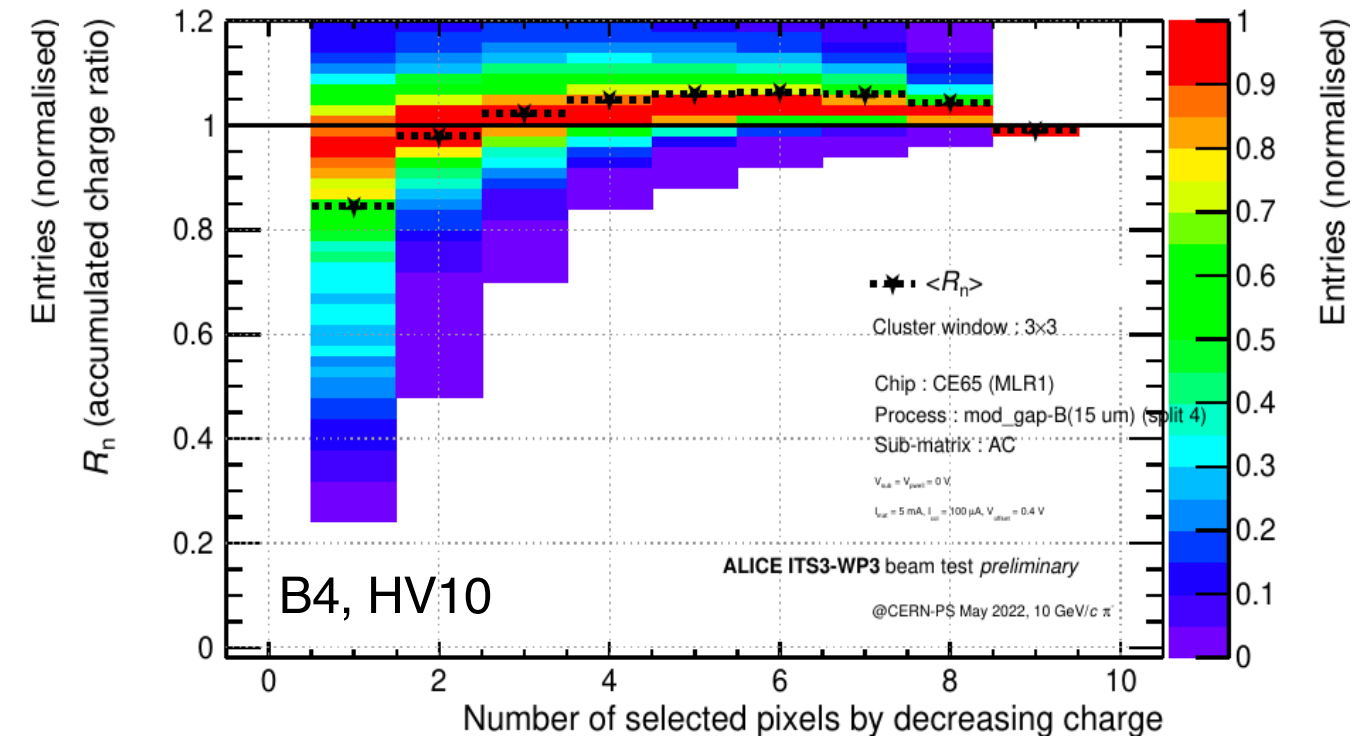
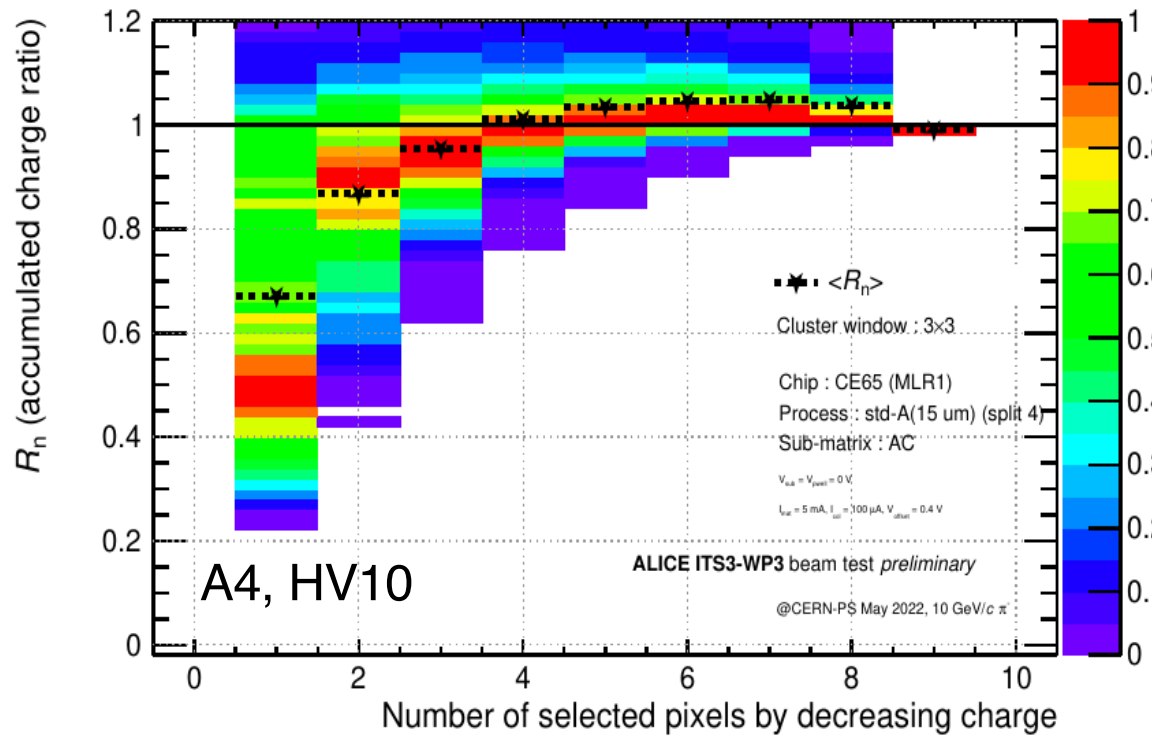
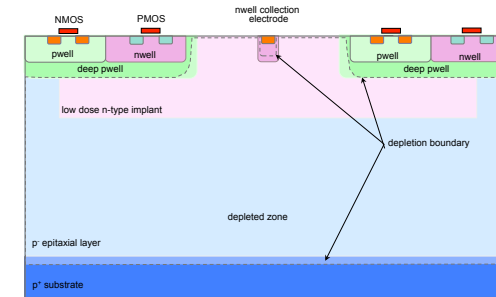
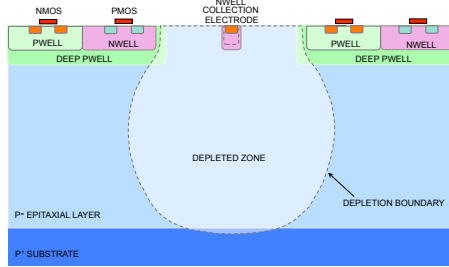


A. Kumar, AIDAInnova 2024

# Process Modification Impact

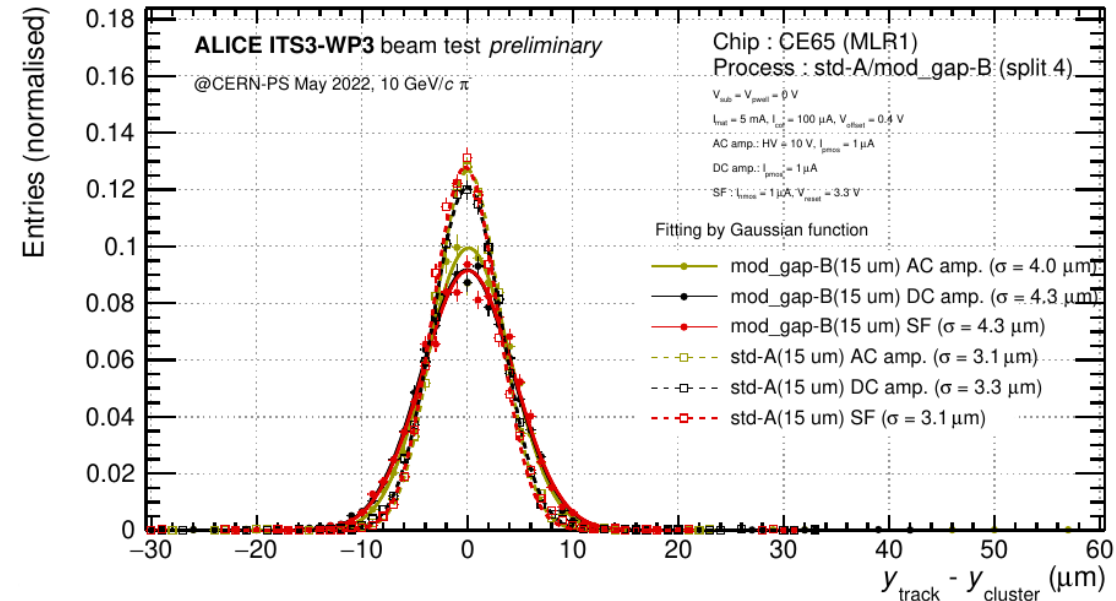
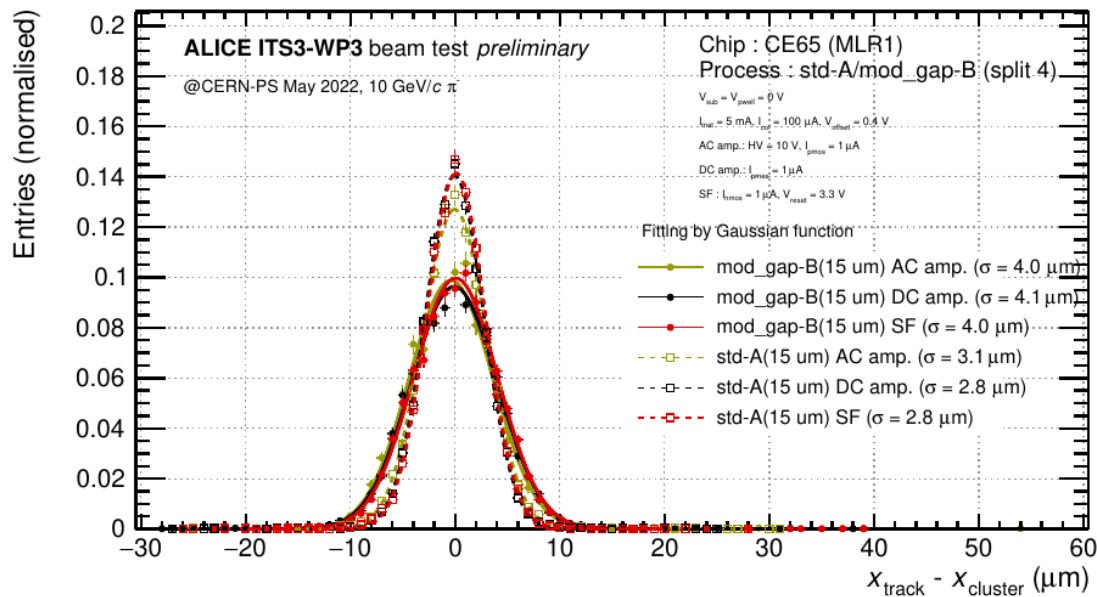
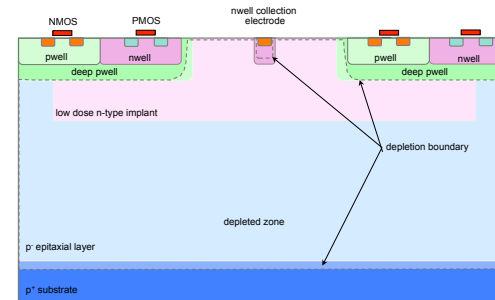
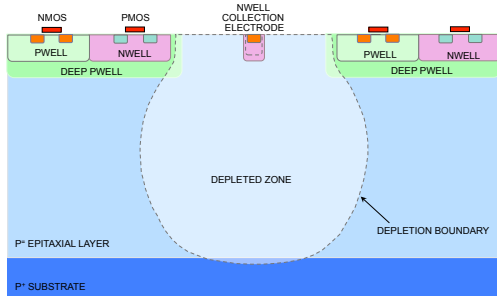


# Process Modification: Charge Sharing



Charge sharing (std) > Charge sharing (mod)

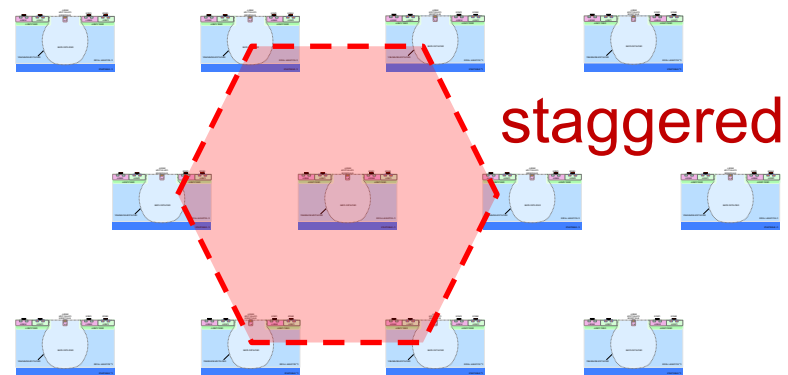
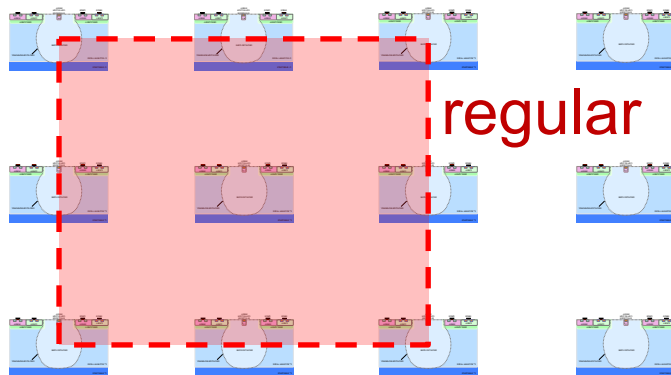
# Process Modification : Spatial Resolution



Residual (std) < Residual (mod)



- AC-coupled
- Three processes (STD, GAP, BLANKET)
- Three pixel pitch values (15  $\mu\text{m}$ , 18  $\mu\text{m}$ , 22.5  $\mu\text{m}$ )
- Pixel arrangement



# Spatial resolution summary

PCB	Geo	Process	Pitch(um)	HV(V)	Sp. Res.(um) (telescope resolution subtracted)
10	SQ	GAP	22.5	10	~5.1
02	SQ	GAP	18	10	~4.1
19	SQ	GAP	15	10	~3.2
18	SQ	STD	22.5	10	~2.4
23	SQ	STD	18	10	~1.8
06	SQ	STD	15	10	~1.3

Telescope resolution: **~2.1um** (Calculated from <https://mmager.web.cern.ch/telescope/tracking.html>)

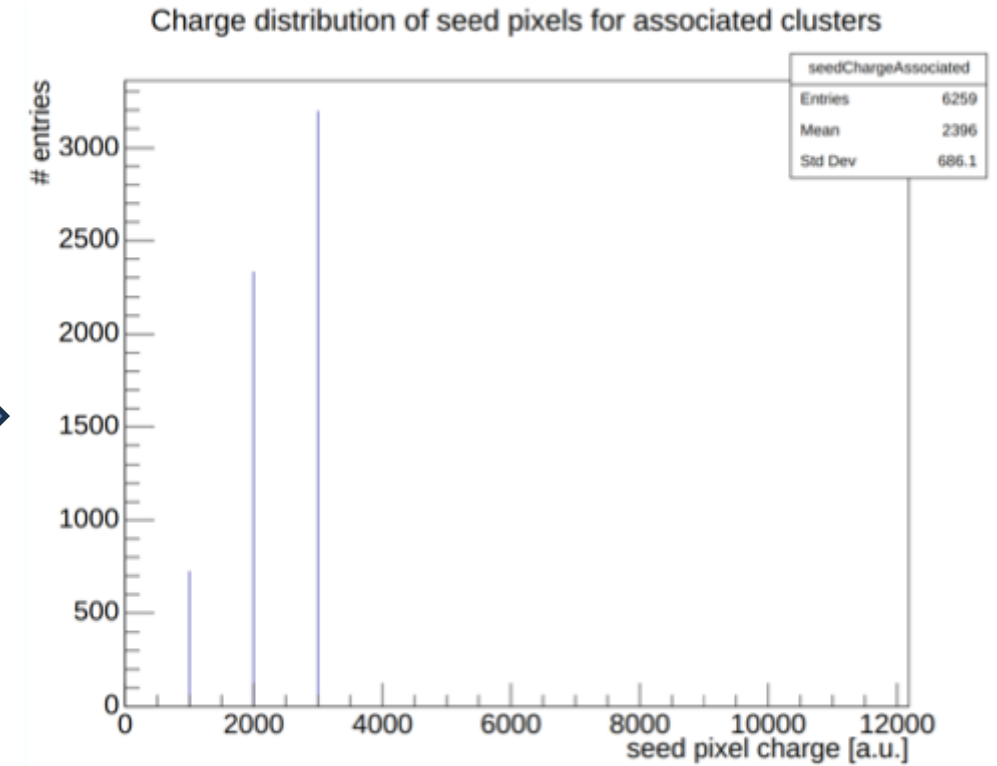
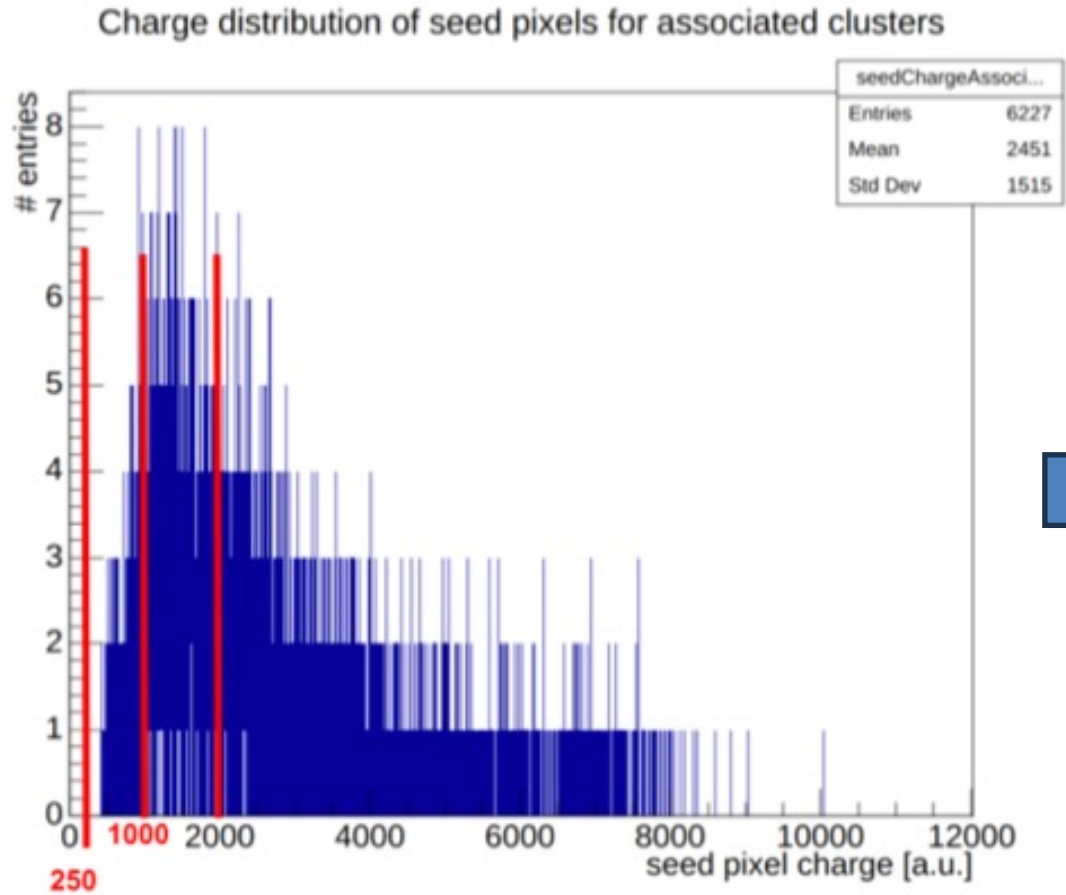
What is required from a sensor?

- Fast Readout → Digital Readout
- Low spatial resolution → Analog Output
- Radiation tolerance...
- etc ....

Is there any trade-off that preserves the spatial resolution without sacrificing the readout speed?

What if we use two bits for digitization, three or maybe four instead of 1 bit?

# Digitization\* : seed pixel signal – 2 bits examples

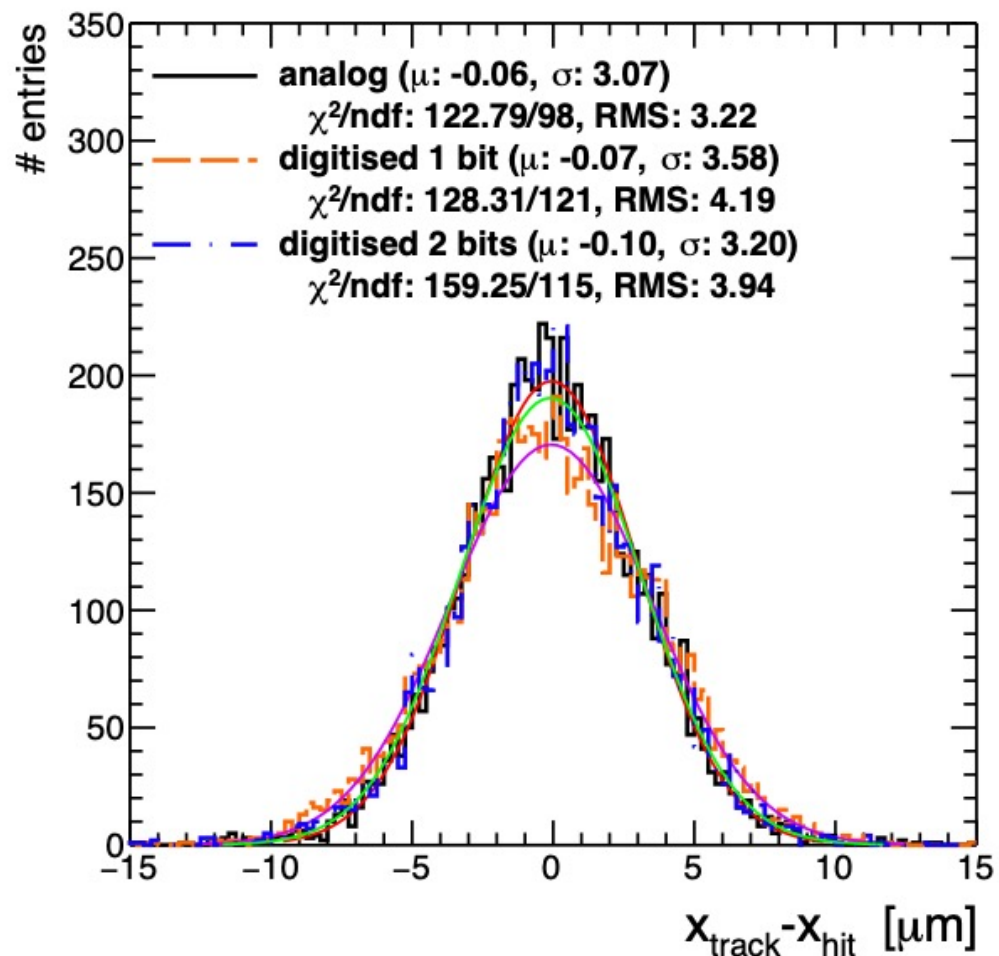


\*PhD Gaëlle SADOWSKI

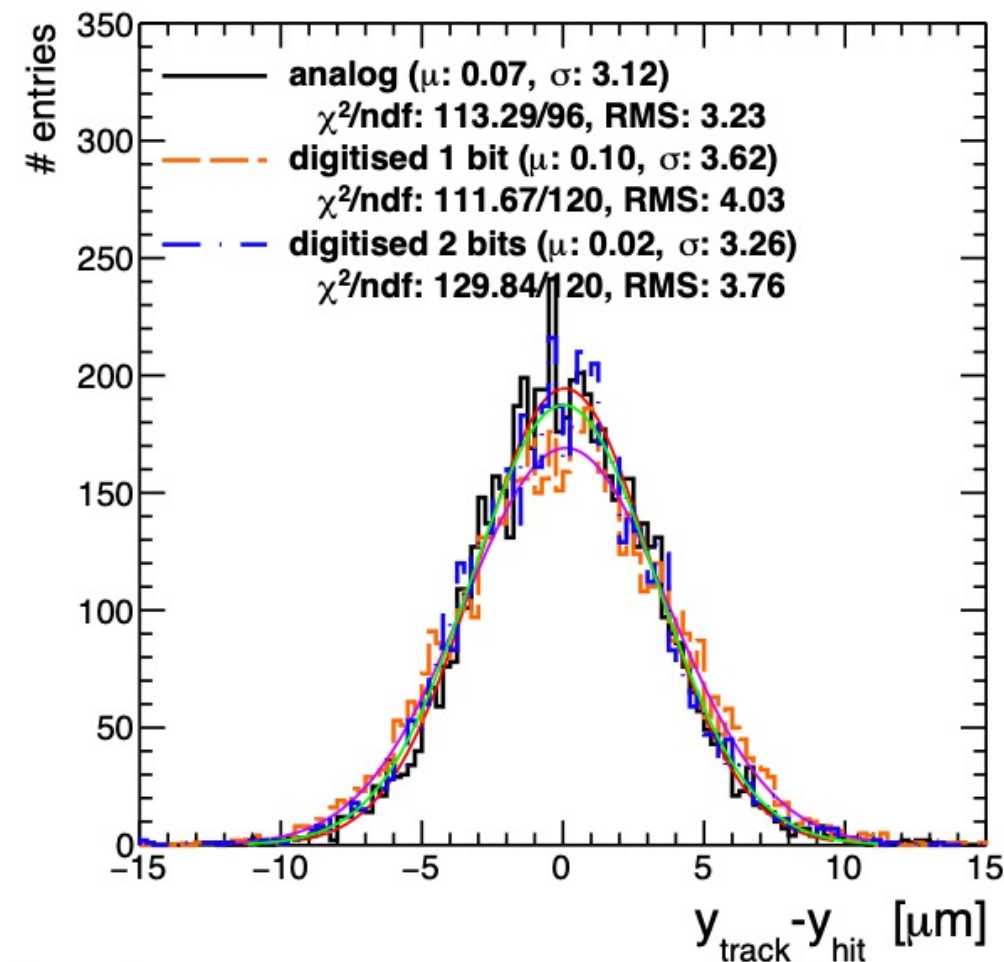


# Digitization\*: the impact of the number of bits on the position residuals

## Residual in global X



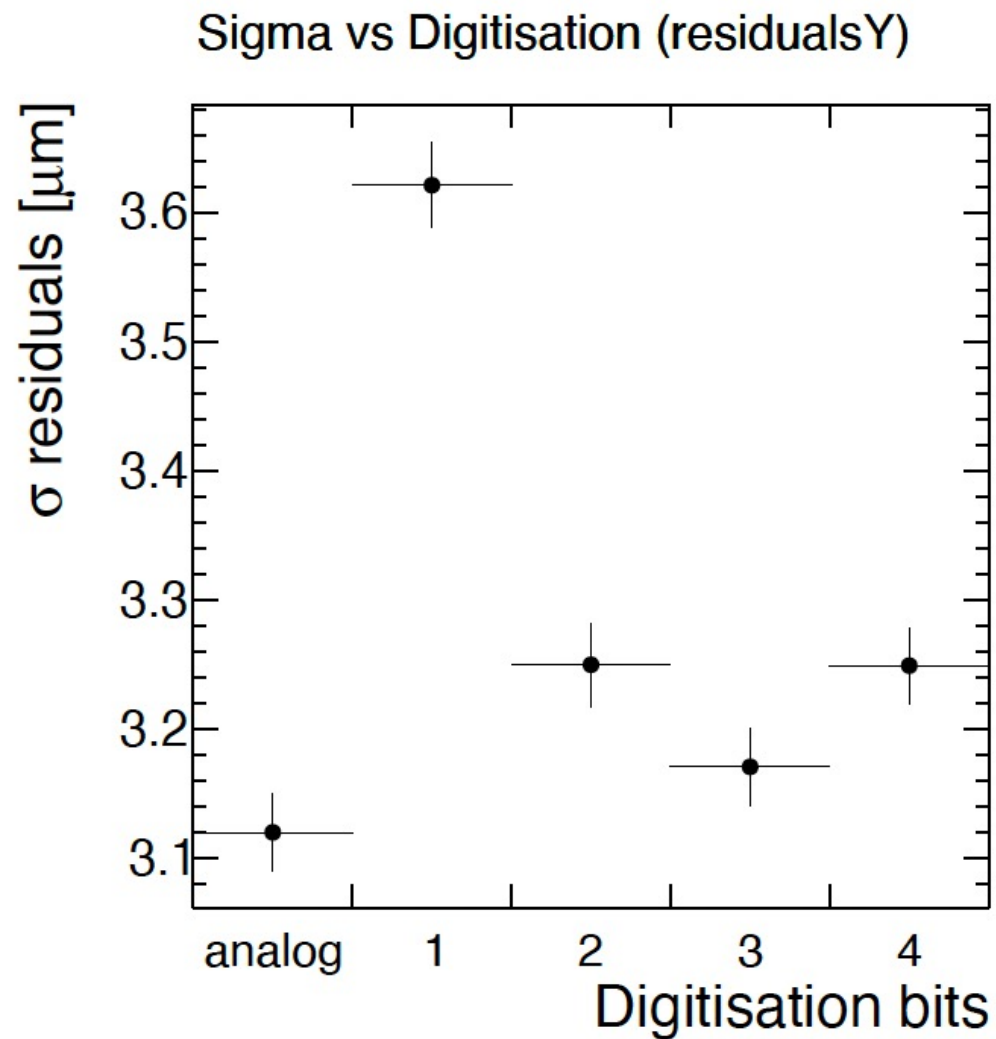
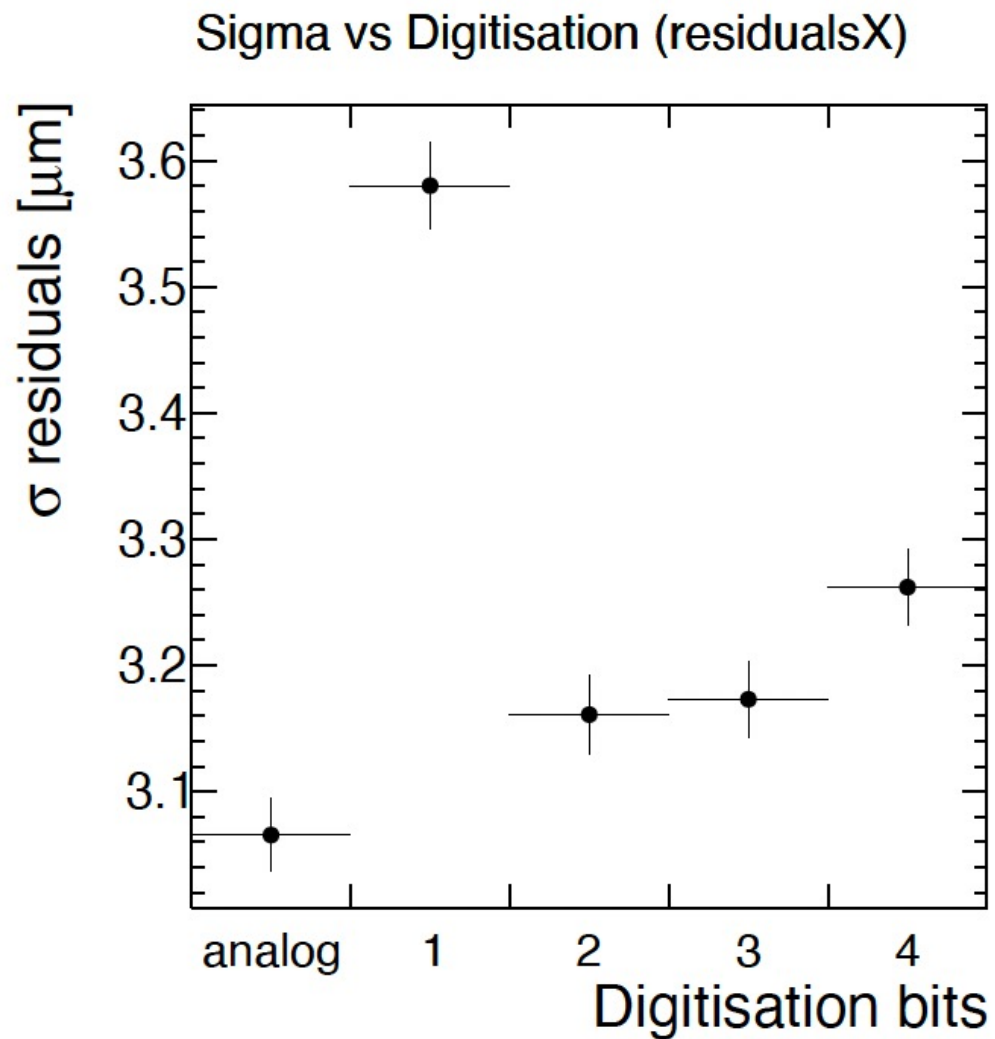
## Residual in global Y



analog  $\rightarrow$  red fit, 1 bit  $\rightarrow$  purple fit, 2 bit  $\rightarrow$  green fit

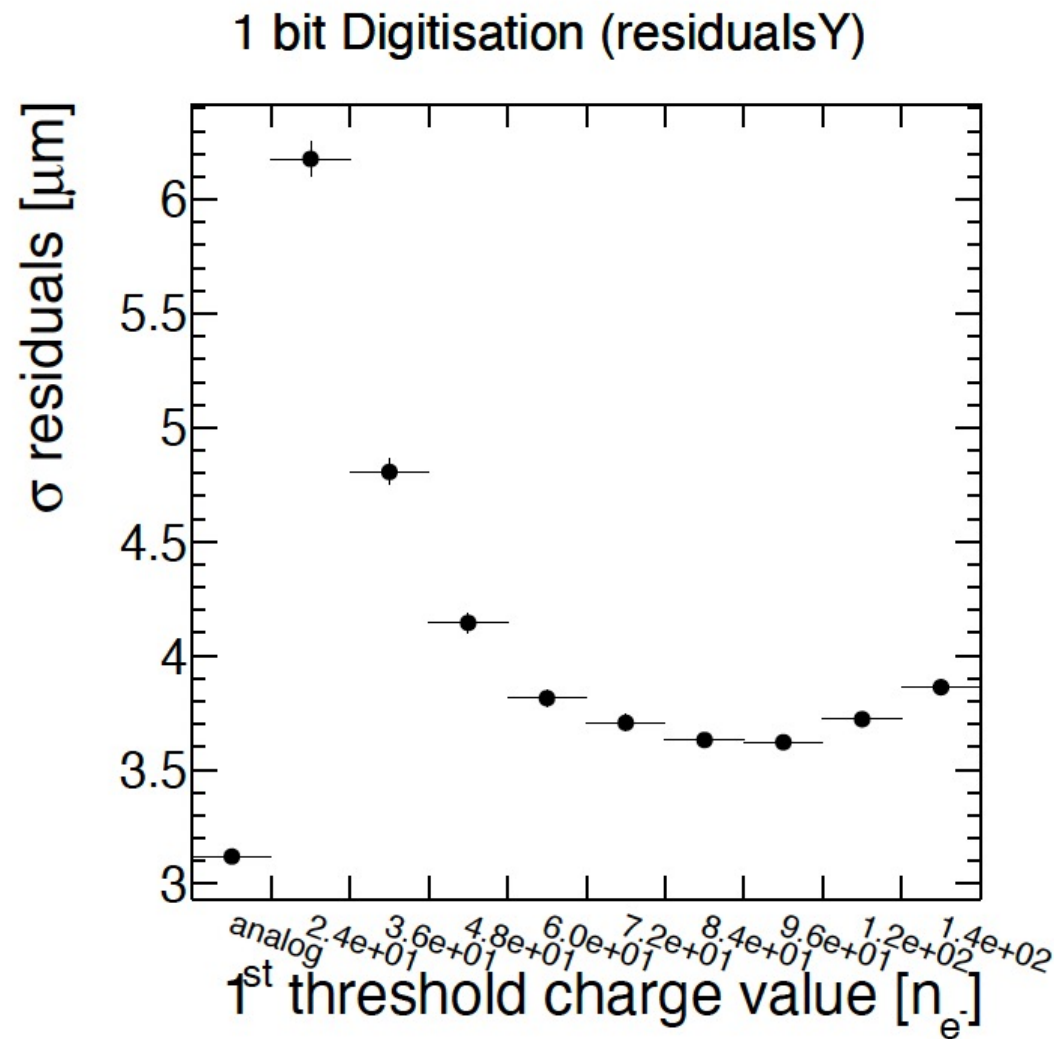
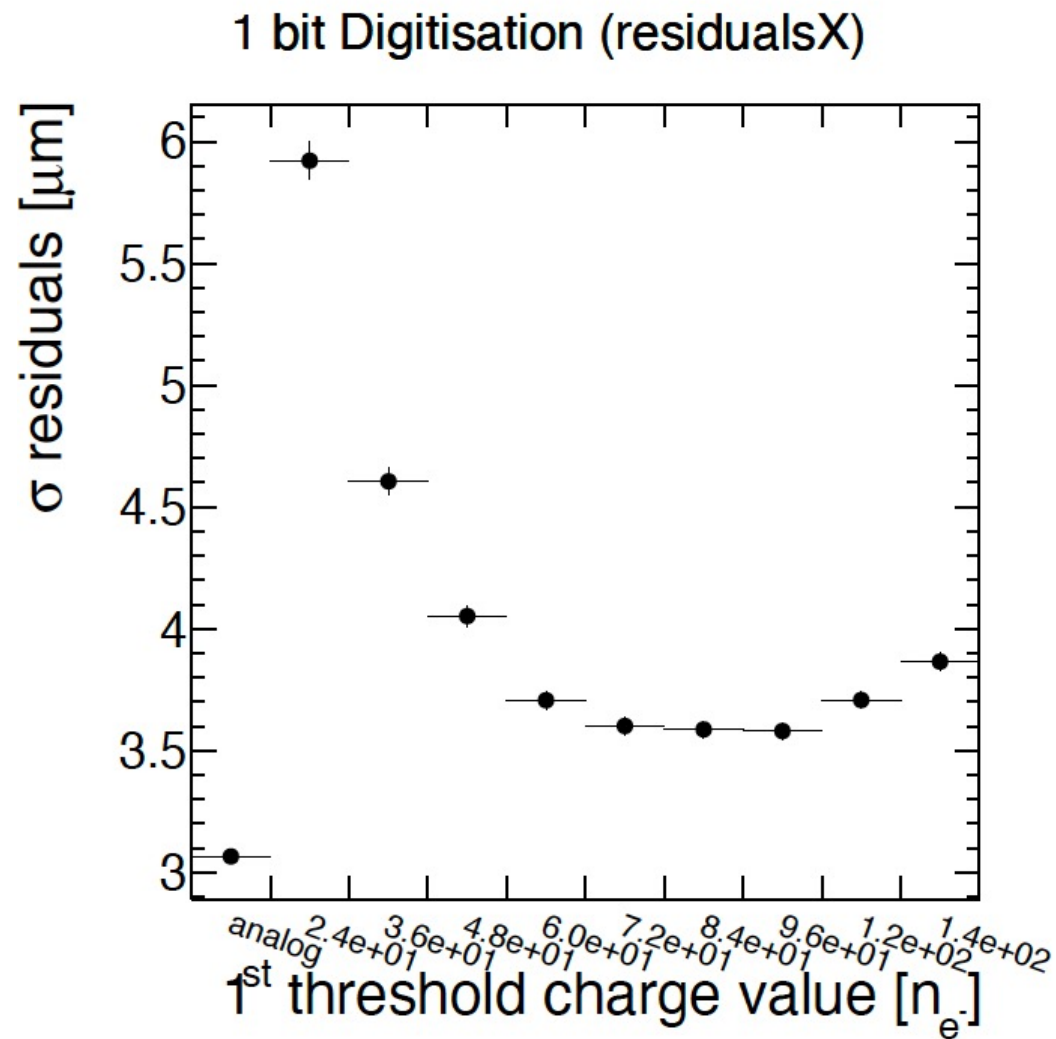
\*PhD Gaëlle SADOWSKI

# Digitization\*: effect of Nbits



\*PhD Gaëlle SADOWSKI

# Digitization: Effect of threshold value on the position residuals



\*PhD Gaëlle SADOWSKI

- MIMOSIS sensor is being continuously improved
- 65 nm Technology is being scrutinized
  - ✓ Impact of pixel pitch
  - ✓ Impact of the process (std, gap, ...)
  - ✓ Impact of pixel geometry
- Digitization is on progress



**Thanks for your attention**